

Freescale Semiconductor, Inc.

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Kinetis KL46 Sub-Family

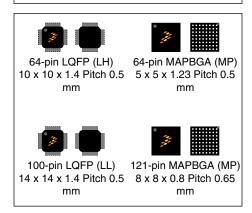
48 MHz Cortex-M0+ Based Microcontroller

Designed with efficiency in mind. Compatible with all other Kinetis L families as well as Kinetis K4x family. General purpose MCU with USB 2.0 and segment LCD, featuring market leading ultra low-power to provide developers an appropriate entry-level 32-bit solution.

This product offers:

- Run power consumption down to 50 μA/MHz in very low power run mode
- Static power consumption down to 2 μA with full state retention and 4.5 µs wakeup
- Ultra-efficient Cortex-M0+ processor running up to 48 MHz with industry leading throughput
- Memory option is up to 256 KB Flash and 32 KB RAM
- Energy-saving architecture is optimized for low power with 90 nm TFS technology, clock and power gating techniques, and zero wait state flash memory controller

MKL46ZxxxVLH4 **MKL46Z256VMP4** MKL46ZxxxVLL4 MKL46ZxxxVMC4



Performance

48 MHz ARM® Cortex®-M0+ core

Memories and memory interfaces

- · Up to 256 KB program flash memory
- Up to 32 KB SRAM

System peripherals

- Nine low-power modes to provide power optimization based on application requirements
- COP Software watchdog
- 4-channel DMA controller, supporting up to 63 request sources
- · Low-leakage wakeup unit
- SWD debug interface and Micro Trace Buffer
- · Bit Manipulation Engine

Clocks

- 32 kHz to 40 kHz or 3 MHz to 32 MHz crystal oscillator
- Multi-purpose clock source

Operating Characteristics

• Voltage range: 1.71 to 3.6 V

• Flash write voltage range: 1.71 to 3.6 V

• Temperature range (ambient): -40 to 105°C

Human-machine interface

- Segment LCD controller supporting up to 47 frontplanes and 8 backplanes, or 51 frontplanes and 4 backplanes
- Low-power hardware touch sensor interface (TSI)
- Up to 84 general-purpose input/output (GPIO)

Communication interfaces

- USB full-/low-speed On-the-Go controller with onchip transceiver and 5 V to 3.3 V regulator
- · Two 16-bit SPI modules
- I2S (SAI) module
- One low power UART module
- · Two UART modules
- · Two I2C module

Analog Modules

- 16-bit SAR ADC
- 12-bit DAC
- · Analog comparator (CMP) containing a 6-bit DAC and programmable reference input

Timers

- Six channel Timer/PWM (TPM)
- Two 2-channel Timer/PWM modules





- Periodic interrupt timers
- 16-bit low-power timer (LPTMR)
- Real time clock

Security and integrity modules

• 80-bit unique identification number per chip

Ordering Information ¹

| Part Number | Memory | | Maximum number of I\O's |
|---------------|------------|-----------|-------------------------|
| | Flash (KB) | SRAM (KB) | |
| MKL46Z128VLH4 | 128 | 16 | 50 |
| MKL46Z256VLH4 | 256 | 32 | 50 |
| MKL46Z256VMP4 | 256 | 32 | 50 |
| MKL46Z128VLL4 | 128 | 16 | 84 |
| MKL46Z256VLL4 | 256 | 32 | 84 |
| MKL46Z128VMC4 | 128 | 16 | 84 |
| MKL46Z256VMC4 | 256 | 32 | 84 |

1. To confirm current availability of ordererable part numbers, go to http://www.freescale.com and perform a part number search.

Related Resources

| Туре | Description | Resource |
|---------------------|--|--|
| Selector Guide | The Freescale Solution Advisor is a web-based tool that features interactive application wizards and a dynamic product selector. | Solution Advisor |
| Reference Manual | The Reference Manual contains a comprehensive description of the structure and function (operation) of a device. | KL46P121M48SF4RM ¹ |
| Data Sheet | The Data Sheet includes electrical characteristics and signal connections. | KL46P121M48SF4 ¹ |
| Chip Errata | The chip mask set Errata provides additional or corrective information for a particular device mask set. | KINETIS_L_xN40H ² |
| Package | Package dimensions are provided in package drawings. | LQFP 64-pin: 98ASS23234W ¹ |
| drawing | | MAPBGA 64-pin: 98ASA00420D1 |
| | | LQFP 100-pin: 98ASS23308W ¹ |
| | | MAPBGA 121-pin: 98ASA00344D1 |

- 1. To find the associated resource, go to http://www.freescale.com and perform a search using this term.
- 2. To find the associated resource, go to http://www.freescale.com and perform a search using this term with the "x" replaced by the revision of the device you are using.



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1 Ratings

1.1 Thermal handling ratings

Table 1. Thermal handling ratings

| Symbol | Description | Min. | Max. | Unit | Notes |
|------------------|-------------------------------|-------------|------|------|-------|
| T _{STG} | Storage temperature | - 55 | 150 | °C | 1 |
| T _{SDR} | Solder temperature, lead-free | _ | 260 | °C | 2 |

- 1. Determined according to JEDEC Standard JESD22-A103, High Temperature Storage Life.
- 2. Determined according to IPC/JEDEC Standard J-STD-020, Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices.

1.2 Moisture handling ratings

Table 2. Moisture handling ratings

| Symbol | Description | Min. | Max. | Unit | Notes |
|--------|----------------------------|------|------|------|-------|
| MSL | Moisture sensitivity level | _ | 3 | _ | 1 |

^{1.} Determined according to IPC/JEDEC Standard J-STD-020, Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices.

1.3 ESD handling ratings

Table 3. ESD handling ratings

| Symbol | Description | Min. | Max. | Unit | Notes |
|------------------|---|-------|-------|------|-------|
| V_{HBM} | Electrostatic discharge voltage, human body model | -2000 | +2000 | V | 1 |
| V _{CDM} | Electrostatic discharge voltage, charged-device model | -500 | +500 | V | 2 |
| I _{LAT} | Latch-up current at ambient temperature of 105 °C | -100 | +100 | mA | 3 |

- 1. Determined according to JEDEC Standard JESD22-A114, *Electrostatic Discharge (ESD) Sensitivity Testing Human Body Model (HBM)*.
- 2. Determined according to JEDEC Standard JESD22-C101, Field-Induced Charged-Device Model Test Method for Electrostatic-Discharge-Withstand Thresholds of Microelectronic Components.
- 3. Determined according to JEDEC Standard JESD78, IC Latch-Up Test.



1.4 Voltage and current operating ratings

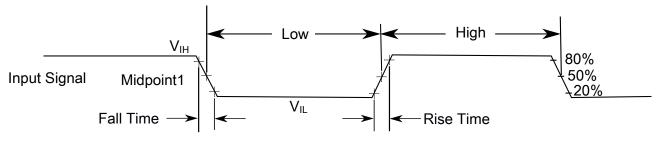
Table 4. Voltage and current operating ratings

| Symbol | Description | Min. | Max. | Unit |
|---------------------|---|-----------------------|-----------------------|------|
| V _{DD} | Digital supply voltage | -0.3 | 3.8 | V |
| I _{DD} | Digital supply current | _ | 120 | mA |
| V _{IO} | IO pin input voltage | -0.3 | V _{DD} + 0.3 | V |
| I _D | Instantaneous maximum current single pin limit (applies to all port pins) | -25 | 25 | mA |
| V_{DDA} | Analog supply voltage | V _{DD} – 0.3 | V _{DD} + 0.3 | V |
| V _{USB_DP} | USB_DP input voltage | -0.3 | 3.63 | V |
| V _{USB_DM} | USB_DM input voltage | -0.3 | 3.63 | V |
| V _{REGIN} | USB regulator input | -0.3 | 6.0 | V |

2 General

2.1 AC electrical characteristics

Unless otherwise specified, propagation delays are measured from the 50% to the 50% point, and rise and fall times are measured at the 20% and 80% points, as shown in the following figure.



The midpoint is $V_{IL} + (V_{IH} - V_{IL}) / 2$

Figure 2. Input signal measurement reference

All digital I/O switching characteristics, unless otherwise specified, assume the output pins have the following characteristics.

- $C_L=30 pF loads$
- Slew rate disabled
- Normal drive strength



2.2 Nonswitching electrical specifications

2.2.1 Voltage and current operating requirements

Table 5. Voltage and current operating requirements

| Symbol | Description | Min. | Max. | Unit | Notes |
|------------------------------------|--|----------------------|----------------------|------|-------|
| V _{DD} | Supply voltage | 1.71 | 3.6 | V | |
| V _{DDA} | Analog supply voltage | 1.71 | 3.6 | V | |
| $V_{DD} - V_{DDA}$ | V _{DD} -to-V _{DDA} differential voltage | -0.1 | 0.1 | V | |
| V _{SS} – V _{SSA} | V _{SS} -to-V _{SSA} differential voltage | -0.1 | 0.1 | V | |
| V _{IH} | Input high voltage | | | | |
| | • 2.7 V ≤ V _{DD} ≤ 3.6 V | $0.7 \times V_{DD}$ | _ | V | |
| | • 1.7 V ≤ V _{DD} ≤ 2.7 V | $0.75 \times V_{DD}$ | _ | V | |
| V _{IL} | Input low voltage | | | | |
| | • 2.7 V ≤ V _{DD} ≤ 3.6 V | _ | $0.35 \times V_{DD}$ | V | |
| | • 1.7 V ≤ V _{DD} ≤ 2.7 V | _ | $0.3 \times V_{DD}$ | V | |
| V _{HYS} | Input hysteresis | $0.06 \times V_{DD}$ | _ | V | |
| licio | IO pin negative DC injection current — single pin • V _{IN} < V _{SS} -0.3V | -3 | _ | mA | 1 |
| I _{ICcont} | Contiguous pin DC injection current —regional limit, includes sum of negative injection currents of 16 contiguous pins • Negative current injection | -25 | _ | mA | |
| V _{ODPU} | Open drain pullup voltage level | V _{DD} | V _{DD} | V | 2 |
| V _{RAM} | V _{DD} voltage required to retain RAM | 1.2 | _ | V | |

^{1.} All I/O pins are internally clamped to V_{SS} through a ESD protection diode. There is no diode connection to V_{DD} . If V_{IN} greater than V_{IO_MIN} (= V_{SS} -0.3 V) is observed, then there is no need to provide current limiting resistors at the pads. If this limit cannot be observed then a current limiting resistor is required. The negative DC injection current limiting resistor is calculated as $R = (V_{IO_MIN} - V_{IN})/|I_{ICIO}|$.

2.2.2 LVD and POR operating requirements

Table 6. V_{DD} supply LVD and POR operating requirements

| Symbol | Description | Min. | Тур. | Max. | Unit | Notes |
|------------------|--|------|------|------|------|-------|
| V _{POR} | Falling V _{DD} POR detect voltage | 0.8 | 1.1 | 1.5 | V | _ |

^{2.} Open drain outputs must be pulled to V_{DD} .



Table 6. V_{DD} supply LVD and POR operating requirements (continued)

| Symbol | Description | Min. | Тур. | Max. | Unit | Notes |
|-------------------|---|------|------|------|------|-------|
| V_{LVDH} | Falling low-voltage detect threshold — high range (LVDV = 01) | 2.48 | 2.56 | 2.64 | V | _ |
| | Low-voltage warning thresholds — high range | | | | | 1 |
| V_{LVW1H} | • Level 1 falling (LVWV = 00) | 2.62 | 2.70 | 2.78 | V | |
| V_{LVW2H} | • Level 2 falling (LVWV = 01) | 2.72 | 2.80 | 2.88 | V | |
| V_{LVW3H} | Level 3 falling (LVWV = 10) | 2.82 | 2.90 | 2.98 | V | |
| V_{LVW4H} | Level 4 falling (LVWV = 11) | 2.92 | 3.00 | 3.08 | V | |
| V _{HYSH} | Low-voltage inhibit reset/recover hysteresis — high range | _ | ±60 | _ | mV | _ |
| V_{LVDL} | Falling low-voltage detect threshold — low range (LVDV=00) | 1.54 | 1.60 | 1.66 | V | _ |
| | Low-voltage warning thresholds — low range | | | | | 1 |
| V_{LVW1L} | • Level 1 falling (LVWV = 00) | 1.74 | 1.80 | 1.86 | V | |
| V_{LVW2L} | • Level 2 falling (LVWV = 01) | 1.84 | 1.90 | 1.96 | V | |
| V_{LVW3L} | • Level 3 falling (LVWV = 10) | 1.94 | 2.00 | 2.06 | V | |
| V_{LVW4L} | Level 4 falling (LVWV = 11) | 2.04 | 2.10 | 2.16 | V | |
| V_{HYSL} | Low-voltage inhibit reset/recover hysteresis — low range | _ | ±40 | _ | mV | _ |
| V_{BG} | Bandgap voltage reference | 0.97 | 1.00 | 1.03 | V | _ |
| t _{LPO} | Internal low power oscillator period — factory trimmed | 900 | 1000 | 1100 | μs | _ |

^{1.} Rising thresholds are falling threshold + hysteresis voltage

2.2.3 Voltage and current operating behaviors

Table 7. Voltage and current operating behaviors

| Symbol | Description | Min. | Max. | Unit | Notes |
|------------------|---|--|--------|--------|-------|
| V _{OH} | Output high voltage — Normal drive pad (except RESET_b) • $2.7 \text{ V} \le \text{V}_{DD} \le 3.6 \text{ V}$, $\text{I}_{OH} = -5 \text{ mA}$ • $1.71 \text{ V} \le \text{V}_{DD} \le 2.7 \text{ V}$, $\text{I}_{OH} = -2.5 \text{ mA}$ | V _{DD} – 0.5 V _{DD} – 0.5 | _ _ | V V | 1, 2 |
| V _{OH} | Output high voltage — High drive pad (except RESET_b) • $2.7 \text{ V} \le \text{V}_{DD} \le 3.6 \text{ V}, \text{I}_{OH} = -20 \text{ mA}$ • $1.71 \text{ V} \le \text{V}_{DD} \le 2.7 \text{ V}, \text{I}_{OH} = -10 \text{ mA}$ | V _{DD} - 0.5 V _{DD} - 0.5 | _ _ | V V | 1, 2 |
| I _{OHT} | Output high current total for all ports | _ | 100 | mA | |



Table 7. Voltage and current operating behaviors (continued)

| Symbol | Description | Min. | Max. | Unit | Notes |
|------------------|--|------|-------|------|-------|
| V _{OL} | Output low voltage — Normal drive pad | | | | 1 |
| | • $2.7 \text{ V} \le \text{V}_{DD} \le 3.6 \text{ V}, \text{I}_{OL} = 5 \text{ mA}$ | _ | 0.5 | V | |
| | • 1.71 V \leq V _{DD} \leq 2.7 V, I _{OL} = 2.5 mA | _ | 0.5 | V | |
| V _{OL} | Output low voltage — High drive pad | | | | 1 |
| | • $2.7 \text{ V} \le \text{V}_{DD} \le 3.6 \text{ V}, \text{I}_{OL} = 20 \text{ mA}$ | _ | 0.5 | V | |
| | • 1.71 V \leq V _{DD} \leq 2.7 V, I _{OL} = 10 mA | _ | 0.5 | V | |
| I _{OLT} | Output low current total for all ports | _ | 100 | mA | |
| I _{IN} | Input leakage current (per pin) for full temperature range | _ | 1 | μA | 3 |
| I _{IN} | Input leakage current (per pin) at 25 °C | _ | 0.025 | μΑ | 3 |
| I _{IN} | Input leakage current (total all pins) for full temperature range | _ | | μA | 3 |
| l _{OZ} | Hi-Z (off-state) leakage current (per pin) | _ | 1 | μΑ | |
| R _{PU} | Internal pullup resistors | 20 | 50 | kΩ | 4 |

^{1.} PTB0, PTB1, PTD6, and PTD7 I/O have both high drive and normal drive capability selected by the associated PTx_PCRn[DSE] control bit. All other GPIOs are normal drive only.

2.2.4 Power mode transition operating behaviors

All specifications except t_{POR} and VLLSx \rightarrow RUN recovery times in the following table assume this clock configuration:

- CPU and system clocks = 48 MHz
- Bus and flash clock = 24 MHz
- FEI clock mode

POR and VLLSx→RUN recovery use FEI clock mode at the default CPU and system frequency of 21 MHz, and a bus and flash clock frequency of 10.5 MHz.

Table 8. Power mode transition operating behaviors

| Symbol | Description | Min. | Тур. | Max. | Unit | Notes |
|------------------|--|------|------|------|------|-------|
| t _{POR} | After a POR event, amount of time from the point V _{DD} reaches 1.8 V to execution of the first instruction across the operating temperature range of the chip. | _ | _ | 300 | μs | 1 |

^{2.} The reset pin only contains an active pull down device when configured as the RESET signal or as a GPIO. When configured as a GPIO output, it acts as a pseudo open drain output.

^{3.} Measured at V_{DD} = 3.6 V

^{4.} Measured at V_{DD} supply voltage = V_{DD} min and Vinput = V_{SS}



Table 8. Power mode transition operating behaviors (continued)

| Symbol | Description | Min. | Тур. | Max. | Unit | Notes |
|--------|---------------|------|------|------|------|-------|
| | VLLS0 → RUN | | | | | |
| | 1220 | _ | 113 | 124 | μs | |
| | • VLLS1 → RUN | | | | | |
| | | _ | 112 | 124 | μs | |
| | VLLS3 → RUN | | | | | |
| | | _ | 53 | 60 | μs | |
| | • LLS → RUN | | | | | |
| | | _ | 4.5 | 5.0 | μs | |
| | VLPS → RUN | | | | | |
| | | _ | 4.5 | 5.0 | μs | |
| | • STOP → RUN | | | | | |
| | | _ | 4.5 | 5.0 | μs | |

^{1.} Normal boot (FTFA_FOPT[LPBOOT]=11).

2.2.5 Power consumption operating behaviors

The maximum values stated in the following table represent characterized results equivalent to the mean plus three times the standard deviation (mean + 3 sigma).

Table 9. Power consumption operating behaviors

| Symbol | Description | | Тур. | Max | Unit | Note |
|---------------------------|---|----------|------|----------|------|------|
| I _{DDA} | Analog supply current | _ | _ | See note | mA | 1 |
| I _{DD_RUNCO_} CM | Run mode current in compute operation - 48 MHz core / 24 MHz flash/ bus disabled, LPTMR running using 4 MHz internal reference clock, CoreMark® benchmark code executing from flash, at 3.0 V | _ | 6.7 | _ | mA | 2 |
| I _{DD_RUNCO} | Run mode current in compute operation - 48 MHz core / 24 MHz flash / bus clock disabled, code of while(1) loop executing from flash, at 3.0 V | _ | 4.5 | 5.1 | mA | 3 |
| I _{DD_RUN} | Run mode current - 48 MHz core / 24 | at 1.8 V | 5.6 | 6.3 | mA | 3 |
| | MHz bus and flash, all peripheral clocks disabled, code executing from flash | at 3.0 V | 5.4 | 6.0 | mA | |
| I _{DD_RUN} | Run mode current - 48 MHz core / 24 MHz bus and flash, all peripheral clocks enabled, code executing from flash, at 1.8 V | _ | 6.9 | 7.3 | mA | 3, 4 |



Table 9. Power consumption operating behaviors (continued)

| Symbol | Description | | Тур. | Max | Unit | Note |
|------------------------|---|-----------|-------|-------|------|------|
| | Run mode current - 48 MHz core / 24 | at 25 °C | 6.9 | 7.1 | mA | |
| | MHz bus and flash, all peripheral clocks enabled, code executing from flash, at 3.0 V | at 125 °C | 7.3 | 7.6 | mA | |
| I _{DD_WAIT} | Wait mode current - core disabled / 48 MHz system / 24 MHz bus / flash disabled (flash doze enabled), all peripheral clocks disabled, at 3.0 V | _ | 2.9 | 3.5 | mA | 3 |
| I _{DD_WAIT} | Wait mode current - core disabled / 24 MHz system / 24 MHz bus / flash disabled (flash doze enabled), wait mode reduced frequency current at 3.0 V — all peripheral clocks disabled | _ | 2.2 | 2.8 | mA | 3 |
| I _{DD_PSTOP2} | Stop mode current with partial stop 2 clocking option - core and system disabled / 10.5 MHz bus, at 3.0 V | _ | 1.6 | 2.1 | mA | 3 |
| DD_VLPRCO _CM | Very-low-power run mode current in compute operation - 4 MHz core / 0.8 MHz flash / bus clock disabled, LPTMR running with 4 MHz internal reference clock, CoreMark benchmark code executing from flash, at 3.0 V | _ | 798 | | μА | 5 |
| I _{DD_VLPRCO} | Very low power run mode current in compute operation - 4 MHz core / 0.8 MHz flash / bus clock disabled, code executing from flash, at 3.0 V | _ | 167 | 336 | μΑ | 6 |
| I _{DD_VLPR} | Very low power run mode current - 4 MHz core / 0.8 MHz bus and flash, all peripheral clocks disabled, code executing from flash, at 3.0 V | _ | 192 | 354 | μА | 6 |
| I _{DD_VLPR} | Very low power run mode current - 4 MHz core / 0.8 MHz bus and flash, all peripheral clocks enabled, code executing from flash, at 3.0 V | _ | 257 | 431 | μА | 4, 6 |
| I _{DD_VLPW} | Very low power wait mode current - core disabled / 4 MHz system / 0.8 MHz bus / flash disabled (flash doze enabled), all peripheral clocks disabled, at 3.0 V | _ | 112 | 286 | μА | 6 |
| I _{DD_STOP} | Stop mode current at 3.0 V | at 25 °C | 306 | 328 | μΑ | _ |
| _ | | at 50 °C | 322 | 349 | μA | 1 |
| | | at 70 °C | 348 | 382 | μΑ | |
| | | at 85 °C | 384 | 433 | μA | |
| | | at 105 °C | 481 | 578 | μA | |
| I _{DD_VLPS} | Very-low-power stop mode current at | at 25 °C | 2.71 | 5.03 | μΑ | _ |
| | 3.0 V | at 50 °C | 7.05 | 11.94 | μΑ | |
| | | at 70 °C | 15.80 | 26.87 | μA | |



Table 9. Power consumption operating behaviors (continued)

| Symbol | Description | | Тур. | Max | Unit | Note |
|-----------------------|--|-----------|-------|--------|------|----------|
| | | at 85 °C | 29.60 | 47.30 | μA | |
| | | at 105 °C | 69.13 | 106.04 | μA | 1 |
| I _{DD_LLS} | Low leakage stop mode current at 3.0 | at 25 °C | 2.00 | 2.7 | μA | _ |
| | V | at 50 °C | 3.96 | 5.14 | μA | 1 |
| | | at 70 °C | 7.77 | 10.71 | μA | 1 |
| | | at 85 °C | 14.15 | 18.79 | μA | 1 |
| | | at 105 °C | 33.20 | 43.67 | μΑ | 1 |
| I _{DD_VLLS3} | Very low-leakage stop mode 3 current | at 25 °C | 1.5 | 2.2 | μΑ | _ |
| | at 3.0 V | at 50 °C | 2.83 | 3.55 | μΑ | 1 |
| | | at 70 °C | 5.53 | 7.26 | μA | 1 |
| | | at 85 °C | 9.92 | 12.71 | μΑ | |
| | | at 105 °C | 22.90 | 29.23 | μΑ | 1 |
| I _{DD_VLLS1} | Very low-leakage stop mode 1 current at 3.0V | at 25 °C | 0.71 | 1.2 | μΑ | _ |
| | | at 50 °C | 1.27 | 1.9 | μΑ | 1 |
| | | at 70 °C | 2.48 | 3.51 | μΑ | |
| | | at 85 °C | 4.65 | 6.29 | μΑ | |
| | | at 105 °C | 11.55 | 14.34 | μΑ | 1 |
| I _{DD_VLLS0} | Very low-leakage stop mode 0 current | at 25 °C | 0.41 | 0.9 | μΑ | <u> </u> |
| | (SMC_STOPCTRL[PORPO] = 0) at 3.0 | at 50 °C | 0.96 | 1.56 | μΑ | 1 |
| | \ v | at 70 °C | 2.17 | 3.1 | μΑ | 1 |
| | | at 85 °C | 4.35 | 5.32 | μA | 1 |
| | | at 105 °C | 11.24 | 14.00 | μΑ | 1 |
| I _{DD_VLLS0} | Very low-leakage stop mode 0 current | at 25 °C | 0.23 | 0.69 | μA | 7 |
| | (SMC_STOPCTRL[PORPO] = 1) at 3.0 V | at 50 °C | 0.77 | 1.35 | μA | 1 |
| | | at 70 °C | 1.98 | 2.52 | μΑ | 1 |
| | | at 85 °C | 4.16 | 5.14 | μA | 1 |
| | | at 105 °C | 11.05 | 13.80 | μA | 1 |

- 1. The analog supply current is the sum of the active or disabled current for each of the analog modules on the device. See each module's specification for its supply current.
- 2. MCG configured for PEE mode. CoreMark benchmark compiled using IAR 6.40 with optimization level high, optimized for balanced.
- 3. MCG configured for FEI mode.
- 4. Incremental current consumption from peripheral activity is not included.
- MCG configured for BLPI mode. CoreMark benchmark compiled using IAR 6.40 with optimization level high, optimized for balanced.
- 6. MCG configured for BLPI mode.
- 7. No brownout.



Table 10. Low power mode peripheral adders — typical value

| Symbol | Description | | | T | empera | ature (°0 | C) | | Unit |
|---|---|--|-----|-----|--------|-----------|-----|-----|------------|
| | | | -40 | 25 | 50 | 70 | 85 | 105 | |
| I _{IREFSTEN4MHz} | 4 MHz internal reference clock Measured by entering STOP o with 4 MHz IRC enabled. | | 56 | 56 | 56 | 56 | 56 | 56 | μA |
| I _{IREFSTEN32KHz} | 32 kHz internal reference clock Measured by entering STOP m 32 kHz IRC enabled. | | 52 | 52 | 52 | 52 | 52 | 52 | μA |
| I _{EREFSTEN4MHz} | External 4 MHz crystal clock at Measured by entering STOP o with the crystal enabled. | | 206 | 228 | 237 | 245 | 251 | 258 | μA |
| I _{EREFSTEN32KHz} | External 32 kHz crystal clock | VLLS1 | 440 | 490 | 540 | 560 | 570 | 580 | nA |
| | adder by means of the OSC0_CR[EREFSTEN and | VLLS3 | 440 | 490 | 540 | 560 | 570 | 580 | |
| | EREFSTEN] bits. Measured | LLS | 490 | 490 | 540 | 560 | 570 | 680 | |
| | by entering all modes with the crystal enabled. | VLPS | 510 | 560 | 560 | 560 | 610 | 680 | |
| | crystal enabled. | STOP | 510 | 560 | 560 | 560 | 610 | 680 | |
| I _{CMP} | CMP peripheral adder measured by placing the device in VLLS1 mode with CMP enabled using the 6-bit DAC and a single external input for compare. Includes 6-bit DAC power consumption. | | 22 | 22 | 22 | 22 | 22 | 22 | μ <i>Α</i> |
| I _{RTC} | RTC peripheral adder measure the device in VLLS1 mode with kHz crystal enabled by means RTC_CR[OSCE] bit and the R for 1 minute. Includes ERCLK3 external crystal) power consum | n external 32 of the TC ALARM set 32K (32 kHz | 432 | 357 | 388 | 475 | 532 | 810 | nA |
| I _{UART} | UART peripheral adder measured by placing the device in STOP or VLPS mode with selected clock source waiting for RX data at | MCGIRCLK (4 MHz internal reference clock) | 66 | 66 | 66 | 66 | 66 | 66 | μA |
| | 115200 baud rate. Includes selected clock source power consumption. | OSCERCLK (4 MHz external crystal) | 214 | 237 | 246 | 254 | 260 | 268 | |
| measured by p device in STOF mode with sele source configu compare gener clock signal. No placed on the I the clock signal selected clock | TPM peripheral adder measured by placing the device in STOP or VLPS mode with selected clock source configured for output | MCGIRCLK (4 MHz internal reference clock) | 86 | 86 | 86 | 86 | 86 | 86 | μA |
| | compare generating 100 Hz clock signal. No load is placed on the I/O generating the clock signal. Includes selected clock source and I/O switching currents. | OSCERCLK (4 MHz external crystal) | 235 | 256 | 265 | 274 | 280 | 287 | |



Table 10. Low power mode peripheral adders — typical value (continued)

| Symbol | Description | | Т | empera | ature (°0 | C) | | Unit |
|------------------|---|-----|-----|--------|-----------|-----|-----|------|
| | | -40 | 25 | 50 | 70 | 85 | 105 | |
| I _{BG} | Bandgap adder when BGEN bit is set and device is placed in VLPx, LLS, or VLLSx mode. | 45 | 45 | 45 | 45 | 45 | 45 | μА |
| I _{ADC} | ADC peripheral adder combining the measured values at V _{DD} and V _{DDA} by placing the device in STOP or VLPS mode. ADC is configured for low power mode using the internal clock and continuous conversions. | 366 | 366 | 366 | 366 | 366 | 366 | μА |
| I _{LCD} | LCD peripheral adder measured by placing the device in VLLS1 mode with external 32 kHz crystal enabled by means of the OSC0_CR[EREFSTEN, EREFSTEN] bits. VIREG disabled, resistor bias network enabled, 1/8 duty cycle, 8 x 36 configuration for driving 288 Segments, 32 Hz frame rate, no LCD glass connected. Includes ERCLK32K (32 kHz external crystal) power consumption. | 5 | 5 | 5 | 5 | 5 | 5 | μΑ |

2.2.5.1 Diagram: Typical IDD_RUN operating behavior

The following data was measured under these conditions:

- MCG in FBE for run mode, and BLPE for VLPR mode
- USB regulator disabled
- No GPIOs toggled
- Code execution from flash with cache enabled
- For the ALLOFF curve, all peripheral clocks are disabled except FTFA



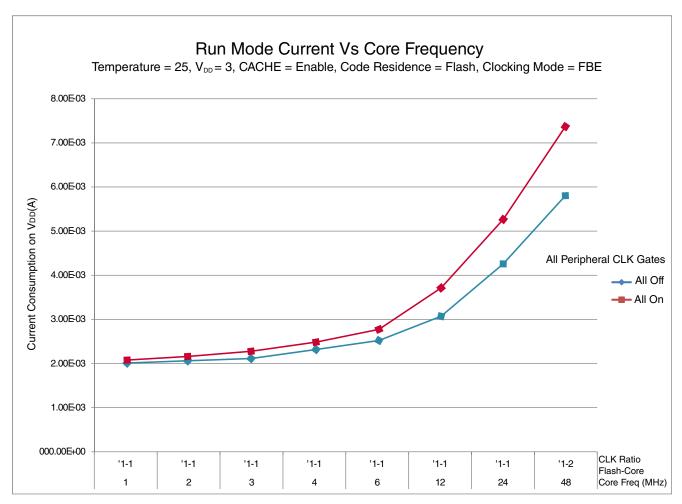


Figure 3. Run mode supply current vs. core frequency



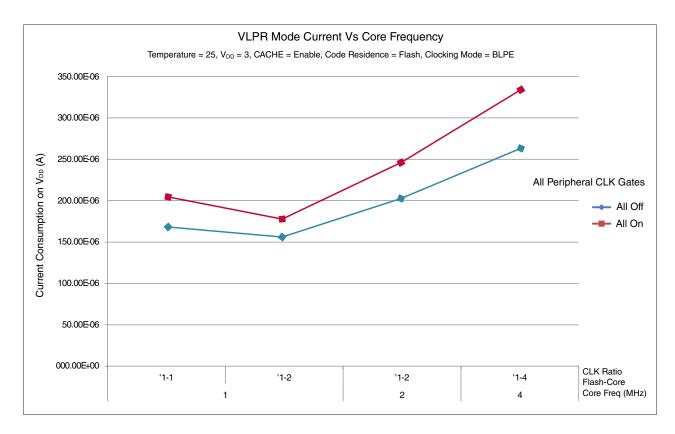


Figure 4. VLPR mode current vs. core frequency

2.2.6 EMC radiated emissions operating behaviors Table 11. EMC radiated emissions operating behaviors

| Symbol | Description | Frequency band (MHz) | Тур. | Unit | Notes |
|---------------------|------------------------------------|----------------------------|------|------|-------|
| V _{RE1} | Radiated emissions voltage, band 1 | 0.15–50 | 12 | dΒμV | 1,2 |
| V _{RE2} | Radiated emissions voltage, band 2 | 50–150 | 8 | dΒμV | |
| V _{RE3} | Radiated emissions voltage, band 3 | 150–500 | 7 | dΒμV | |
| V _{RE4} | Radiated emissions voltage, band 4 | 500-1000 | 4 | dΒμV | |
| V _{RE_IEC} | IEC level | 0.15-1000 | М | _ | 2,3 |

- Determined according to IEC Standard 61967-1, Integrated Circuits Measurement of Electromagnetic Emissions, 150 kHz to 1 GHz Part 1: General Conditions and Definitions and IEC Standard 61967-2, Integrated Circuits -Measurement of Electromagnetic Emissions, 150 kHz to 1 GHz Part 2: Measurement of Radiated Emissions—TEM Cell and Wideband TEM Cell Method. Measurements were made while the microcontroller was running basic application code. The reported emission level is the value of the maximum measured emission, rounded up to the next whole number, from among the measured orientations in each frequency range.
- 2. $V_{DD} = 3.3 \text{ V}$, $T_A = 25 \,^{\circ}\text{C}$, $f_{OSC} = 8 \, \text{MHz}$ (crystal), $f_{SYS} = 48 \, \text{MHz}$, $f_{BUS} = 24 \, \text{MHz}$
- 3. Specified according to Annex D of IEC Standard 61967-2, Measurement of Radiated Emissions—TEM Cell and Wideband TEM Cell Method



2.2.7 Designing with radiated emissions in mind

To find application notes that provide guidance on designing your system to minimize interference from radiated emissions:

- 1. Go to www.freescale.com.
- 2. Perform a keyword search for "EMC design."

2.2.8 Capacitance attributes

Table 12. Capacitance attributes

| Symbol | Description | Min. | Max. | Unit |
|-----------------|-------------------|------|------|------|
| C _{IN} | Input capacitance | _ | 7 | pF |

2.3 Switching specifications

2.3.1 Device clock specifications

Table 13. Device clock specifications

| Symbol | Description | Min. | Max. | Unit |
|--------------------------|---|------|------|------|
| | Normal run mode | • | • | • |
| f _{SYS} | System and core clock | _ | 48 | MHz |
| f _{BUS} | Bus clock | _ | 24 | MHz |
| f _{FLASH} | Flash clock | _ | 24 | MHz |
| f _{SYS_USB} | System and core clock when Full Speed USB in operation | 20 | _ | MHz |
| f _{LPTMR} | LPTMR clock | _ | 24 | MHz |
| | VLPR and VLPS modes ¹ | • | | |
| f _{SYS} | System and core clock | _ | 4 | MHz |
| f _{BUS} | Bus clock | _ | 1 | MHz |
| f _{FLASH} | Flash clock | _ | 1 | MHz |
| f _{LPTMR} | LPTMR clock ² | _ | 24 | MHz |
| f _{ERCLK} | External reference clock | _ | 16 | MHz |
| f _{LPTMR_ERCLK} | LPTMR external reference clock | _ | 16 | MHz |
| f _{osc_hi_2} | Oscillator crystal or resonator frequency — high frequency mode (high range) (MCG_C2[RANGE]=1x) | _ | 16 | MHz |
| f _{TPM} | TPM asynchronous clock | _ | 8 | MHz |
| f _{UART0} | UART0 asynchronous clock | _ | 8 | MHz |



- The frequency limitations in VLPR and VLPS modes here override any frequency specification listed in the timing specification for any other module. These same frequency limits apply to VLPS, whether VLPS was entered from RUN or from VLPR.
- 2. The LPTMR can be clocked at this speed in VLPR or VLPS only when the source is an external pin.

2.3.2 General switching specifications

These general-purpose specifications apply to all signals configured for GPIO and UART signals.

Table 14. General switching specifications

| Description | Min. | Max. | Unit | Notes |
|---|------|------|---------------------|-------|
| GPIO pin interrupt pulse width (digital glitch filter disabled) — Synchronous path | 1.5 | _ | Bus clock cycles | 1 |
| External RESET and NMI pin interrupt pulse width — Asynchronous path | 100 | _ | ns | 2 |
| GPIO pin interrupt pulse width — Asynchronous path | 16 | _ | ns | 2 |
| Port rise and fall time | _ | 36 | ns | 3 |

- 1. The greater synchronous and asynchronous timing must be met.
- 2. This is the shortest pulse that is guaranteed to be recognized.
- 3. 75 pF load

2.4 Thermal specifications

2.4.1 Thermal operating requirements

Table 15. Thermal operating requirements

| Symbol | Description | Min. | Max. | Unit |
|----------------|--------------------------|------|------|------|
| T _J | Die junction temperature | -40 | 125 | °C |
| T _A | Ambient temperature | -40 | 105 | °C |



2.4.2 Thermal attributes

Table 16. Thermal attributes

| Board type | Symbol | Description | 121 MAPBG A | 100 LQFP | 64 LQFP | 64 MAPBG A | Unit | Notes |
|-------------------|-------------------|---|-------------------|-------------|------------|------------------|------|-------|
| Single-layer (1S) | $R_{\theta JA}$ | Thermal resistance, junction to ambient (natural convection) | 94 | 64 | 69 | 49.8 | °C/W | 1 |
| Four-layer (2s2p) | $R_{\theta JA}$ | Thermal resistance, junction to ambient (natural convection) | 57 | 51 | 51 | 42.3 | °C/W | |
| Single-layer (1S) | R _{θJMA} | Thermal resistance, junction to ambient (200 ft./min. air speed) | 81 | 54 | 58 | 40.9 | °C/W | |
| Four-layer (2s2p) | R _{θJMA} | Thermal resistance, junction to ambient (200 ft./min. air speed) | 53 | 45 | 44 | 37.7 | °C/W | |
| _ | R _{θJB} | Thermal resistance, junction to board | 40 | 37 | 33 | 39.2 | °C/W | 2 |
| _ | R _{0JC} | Thermal resistance, junction to case | 30 | 19 | 19 | 50.3 | °C/W | 3 |
| _ | $\Psi_{ m JT}$ | Thermal characterization parameter, junction to package top outside center (natural convection) | 8 | 4 | 4 | 2.2 | °C/W | 4 |

- 1. Determined according to JEDEC Standard JESD51-2, Integrated Circuits Thermal Test Method Environmental Conditions—Natural Convection (Still Air), or EIA/JEDEC Standard JESD51-6, Integrated Circuit Thermal Test Method Environmental Conditions—Forced Convection (Moving Air).
- 2. Determined according to JEDEC Standard JESD51-8, *Integrated Circuit Thermal Test Method Environmental Conditions—Junction-to-Board*.
- 3. Determined according to Method 1012.1 of MIL-STD 883, *Test Method Standard, Microcircuits*, with the cold plate temperature used for the case temperature. The value includes the thermal resistance of the interface material between the top of the package and the cold plate.
- 4. Determined according to JEDEC Standard JESD51-2, *Integrated Circuits Thermal Test Method Environmental Conditions—Natural Convection (Still Air)*.

3 Peripheral operating requirements and behaviors

3.1 Core modules



3.1.1 SWD electricals

Table 17. SWD full voltage range electricals

| Symbol | Description | Min. | Max. | Unit |
|--------|---|------|------|------|
| | Operating voltage | 1.71 | 3.6 | V |
| J1 | SWD_CLK frequency of operation | | | |
| | Serial wire debug | 0 | 25 | MHz |
| J2 | SWD_CLK cycle period | 1/J1 | _ | ns |
| J3 | SWD_CLK clock pulse width | | | |
| | Serial wire debug | 20 | _ | ns |
| J4 | SWD_CLK rise and fall times | _ | 3 | ns |
| J9 | SWD_DIO input data setup time to SWD_CLK rise | 10 | _ | ns |
| J10 | SWD_DIO input data hold time after SWD_CLK rise | 0 | _ | ns |
| J11 | SWD_CLK high to SWD_DIO data valid | _ | 32 | ns |
| J12 | SWD_CLK high to SWD_DIO high-Z | 5 | _ | ns |

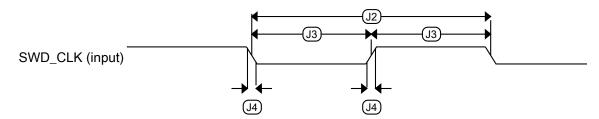


Figure 5. Serial wire clock input timing



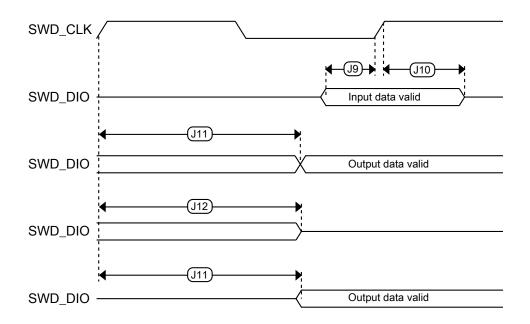


Figure 6. Serial wire data timing

3.2 System modules

There are no specifications necessary for the device's system modules.

3.3 Clock modules

3.3.1 MCG specifications

Table 18. MCG specifications

| Symbol | Description | Min. | Тур. | Max. | Unit | Notes |
|-------------------------|--|-------|--------|---------|-------------------|-------|
| f _{ints_ft} | Internal reference frequency (slow clock) — factory trimmed at nominal V _{DD} and 25 °C | _ | 32.768 | _ | kHz | |
| f _{ints_t} | Internal reference frequency (slow clock) — user trimmed | 31.25 | _ | 39.0625 | kHz | |
| $\Delta_{fdco_res_t}$ | Resolution of trimmed average DCO output frequency at fixed voltage and temperature — using C3[SCTRIM] and C4[SCFTRIM] | _ | ± 0.3 | ± 0.6 | %f _{dco} | 1 |



Table 18. MCG specifications (continued)

| Symbol | Description | | Min. | Тур. | Max. | Unit | Notes |
|--------------------------|---|---|---------------------------------|-----------|---------|-----------------------|-------|
| Δf_{dco_t} | | trimmed average DCO output Itage and temperature | _ | +0.5/-0.7 | ± 3 | %f _{dco} | 1, 2 |
| Δf_{dco_t} | | trimmed average DCO output ed voltage and temperature | _ | ± 0.4 | ± 1.5 | %f _{dco} | 1, 2 |
| f _{intf_ft} | | frequency (fast clock) — nominal V _{DD} and 25 °C | _ | 4 | _ | MHz | |
| ∆f _{intf_ft} | (fast clock) over te | on of internal reference clock emperature and voltage — nominal V _{DD} and 25 °C | _ | +1/-2 | ± 3 | %f _{intf_ft} | 2 |
| f _{intf_t} | Internal reference trimmed at nomina | frequency (fast clock) — user al V _{DD} and 25 °C | 3 | _ | 5 | MHz | |
| f _{loc_low} | Loss of external c | lock minimum frequency — | (3/5) x f _{ints_t} | _ | _ | kHz | |
| f _{loc_high} | Loss of external c | lock minimum frequency — | (16/5) x f _{ints_t} | _ | _ | kHz | |
| | | FI | LL | • | | | |
| f _{fII_ref} | FLL reference free | quency range | 31.25 | _ | 39.0625 | kHz | |
| f _{dco} | DCO output frequency range | Low range (DRS = 00) 640 × f _{fll ref} | 20 | 20.97 | 25 | MHz | 3, 4 |
| | | Mid range (DRS = 01) $1280 \times f_{fill ref}$ | 40 | 41.94 | 48 | MHz | |
| f _{dco_t_DMX3} | DCO output frequency | Low range (DRS = 00) $732 \times f_{fil\ ref}$ | _ | 23.99 | _ | MHz | 5, 6 |
| | | Mid range (DRS = 01) $1464 \times f_{fil_ref}$ | _ | 47.97 | _ | MHz | |
| J _{cyc_fll} | FLL period jitter | | _ | 180 | _ | ps | 7 |
| | • f _{VCO} = 48 M | Hz | | | | | |
| t _{fII_acquire} | FLL target frequer | ncy acquisition time | _ | _ | 1 | ms | 8 |
| | <u> </u> | PI | LL | 1 | | | |
| f _{vco} | VCO operating fre | equency | 48.0 | _ | 100 | MHz | |
| I _{pll} | | rent Hz (f _{osc_hi_1} = 8 MHz, f _{pll_ref} = V multiplier = 48) | _ | 1060 | _ | μА | 9 |
| I _{pll} | | rent IHz (f _{osc_hi_1} = 8 MHz, f _{pll_ref} = V multiplier = 24) | _ | 600 | _ | μΑ | 9 |
| f _{pll_ref} | PLL reference free | quency range | 2.0 | _ | 4.0 | MHz | |
| J _{cyc_pll} | PLL period jitter (F | RMS) | | | | | 10 |
| | | | | 100 | | | |
| | f_{vco} = 48 MH | łz | _ | 120 | _ | ps | |



| Symbol | Description | Min. | Тур. | Max. | Unit | Notes |
|-----------------------|---------------------------------------|--------|------|-------------------------------------|------|-------|
| J _{acc_pll} | PLL accumulated jitter over 1µs (RMS) | | | | | 10 |
| | • f _{vco} = 48 MHz | _ | 1350 | _ | ps | |
| | • f _{vco} = 100 MHz | _ | 600 | _ | ps | |
| D _{lock} | Lock entry frequency tolerance | ± 1.49 | _ | ± 2.98 | % | |
| D _{unl} | Lock exit frequency tolerance | ± 4.47 | _ | ± 5.97 | % | |
| t _{pll_lock} | Lock detector detection time | _ | _ | 150 × 10 ⁻⁶ + 1075(1/ | S | 11 |
| | | | | f _{pll_ref}) | | |

- This parameter is measured with the internal reference (slow clock) being used as a reference to the FLL (FEI clock mode).
- 2. The deviation is relative to the factory trimmed frequency at nominal VDD and 25 °C, fints ft.
- 3. These typical values listed are with the slow internal reference clock (FEI) using factory trim and DMX32 = 0.
- 4. The resulting system clock frequencies must not exceed their maximum specified values. The DCO frequency deviation (Δf_{dco-t}) over voltage and temperature must be considered.
- 5. These typical values listed are with the slow internal reference clock (FEI) using factory trim and DMX32 = 1.
- 6. The resulting clock frequency must not exceed the maximum specified clock frequency of the device.
- 7. This specification is based on standard deviation (RMS) of period or frequency.
- 8. This specification applies to any time the FLL reference source or reference divider is changed, trim value is changed, DMX32 bit is changed, DRS bits are changed, or changing from FLL disabled (BLPE, BLPI) to FLL enabled (FEI, FEE, FBE, FBI). If a crystal/resonator is being used as the reference, this specification assumes it is already running.
- 9. Excludes any oscillator currents that are also consuming power while PLL is in operation.
- 10. This specification was obtained using a Freescale developed PCB. PLL jitter is dependent on the noise characteristics of each PCB and results will vary.
- 11. This specification applies to any time the PLL VCO divider or reference divider is changed, or changing from PLL disabled (BLPE, BLPI) to PLL enabled (PBE, PEE). If a crystal/resonator is being used as the reference, this specification assumes it is already running.

3.3.2 Oscillator electrical specifications

3.3.2.1 Oscillator DC electrical specifications Table 19. Oscillator DC electrical specifications

| Symbol | Description | Min. | Тур. | Max. | Unit | Notes |
|--------------------|---|------|------|------|------|-------|
| V _{DD} | Supply voltage | 1.71 | _ | 3.6 | V | |
| I _{DDOSC} | Supply current — low-power mode (HGO=0) | | | | | 1 |
| | • 32 kHz | _ | 500 | _ | nA | |
| | • 4 MHz | _ | 200 | _ | μΑ | |
| | • 8 MHz (RANGE=01) | _ | 300 | _ | μA | |
| | • 16 MHz | _ | 950 | _ | μA | |
| | | _ | 1.2 | _ | mA | |



Table 19. Oscillator DC electrical specifications (continued)

| Symbol | Description | Min. | Тур. | Max. | Unit | Notes |
|------------------------------|--|------|-----------------|------|------|-------|
| | • 24 MHz | _ | 1.5 | _ | mA | |
| | • 32 MHz | | | | | |
| I _{DDOSC} | Supply current — high gain mode (HGO=1) | | | | | 1 |
| | • 32 kHz | _ | 25 | _ | μΑ | |
| | • 4 MHz | _ | 400 | _ | μΑ | |
| | • 8 MHz (RANGE=01) | _ | 500 | _ | μΑ | |
| | • 16 MHz | _ | 2.5 | _ | mA | |
| | • 24 MHz | _ | 3 | _ | mA | |
| | • 32 MHz | _ | 4 | _ | mA | |
| C _x | EXTAL load capacitance | _ | _ | _ | | 2, 3 |
| C _y | XTAL load capacitance | _ | _ | _ | | 2, 3 |
| R _F | Feedback resistor — low-frequency, low-power mode (HGO=0) | _ | _ | _ | ΜΩ | 2, 4 |
| | Feedback resistor — low-frequency, high-gain mode (HGO=1) | _ | 10 | _ | ΜΩ | |
| | Feedback resistor — high-frequency, low-power mode (HGO=0) | _ | _ | _ | MΩ | |
| | Feedback resistor — high-frequency, high-gain mode (HGO=1) | _ | 1 | _ | ΜΩ | |
| R _S | Series resistor — low-frequency, low-power mode (HGO=0) | _ | _ | _ | kΩ | |
| | Series resistor — low-frequency, high-gain mode (HGO=1) | _ | 200 | _ | kΩ | |
| | Series resistor — high-frequency, low-power mode (HGO=0) | _ | _ | _ | kΩ | |
| | Series resistor — high-frequency, high-gain mode (HGO=1) | | | | | |
| | | _ | 0 | _ | kΩ | |
| V _{pp} ⁵ | Peak-to-peak amplitude of oscillation (oscillator mode) — low-frequency, low-power mode (HGO=0) | _ | 0.6 | _ | V | |
| | Peak-to-peak amplitude of oscillation (oscillator mode) — low-frequency, high-gain mode (HGO=1) | _ | V _{DD} | _ | V | |
| | Peak-to-peak amplitude of oscillation (oscillator mode) — high-frequency, low-power mode (HGO=0) | _ | 0.6 | _ | V | |
| | Peak-to-peak amplitude of oscillation (oscillator mode) — high-frequency, high-gain mode (HGO=1) | _ | V _{DD} | _ | V | |

^{1.} V_{DD} =3.3 V, Temperature =25 °C 2. See crystal or resonator manufacturer's recommendation



Peripheral operating requirements and behaviors

- 3. C_x , C_y can be provided by using the integrated capacitors when the low frequency oscillator (RANGE = 00) is used. For all other cases external capacitors must be used.
- 4. When low power mode is selected, R_F is integrated and must not be attached externally.
- 5. The EXTAL and XTAL pins should only be connected to required oscillator components and must not be connected to any other devices.

3.3.2.2 Oscillator frequency specifications Table 20. Oscillator frequency specifications

| Symbol | Description | Min. | Тур. | Max. | Unit | Notes |
|-----------------------|---|------|------|------|------|-------|
| f _{osc_lo} | Oscillator crystal or resonator frequency — low-frequency mode (MCG_C2[RANGE]=00) | 32 | _ | 40 | kHz | |
| f _{osc_hi_1} | Oscillator crystal or resonator frequency — high-frequency mode (low range) (MCG_C2[RANGE]=01) | 3 | _ | 8 | MHz | |
| f _{osc_hi_2} | Oscillator crystal or resonator frequency — high frequency mode (high range) (MCG_C2[RANGE]=1x) | 8 | _ | 32 | MHz | |
| f _{ec_extal} | Input clock frequency (external clock mode) | _ | _ | 48 | MHz | 1, 2 |
| t _{dc_extal} | Input clock duty cycle (external clock mode) | 40 | 50 | 60 | % | |
| t _{cst} | Crystal startup time — 32 kHz low-frequency, low-power mode (HGO=0) | _ | 750 | _ | ms | 3, 4 |
| | Crystal startup time — 32 kHz low-frequency, high-gain mode (HGO=1) | _ | 250 | _ | ms | |
| | Crystal startup time — 8 MHz high-frequency (MCG_C2[RANGE]=01), low-power mode (HGO=0) | _ | 0.6 | _ | ms | |
| | Crystal startup time — 8 MHz high-frequency (MCG_C2[RANGE]=01), high-gain mode (HGO=1) | _ | 1 | _ | ms | |

- 1. Other frequency limits may apply when external clock is being used as a reference for the FLL or PLL.
- 2. When transitioning from FEI or FBI to FBE mode, restrict the frequency of the input clock so that, when it is divided by FRDIV, it remains within the limits of the DCO input clock frequency.
- 3. Proper PC board layout procedures must be followed to achieve specifications.
- 4. Crystal startup time is defined as the time between the oscillator being enabled and the OSCINIT bit in the MCG_S register being set.

3.4 Memories and memory interfaces

3.4.1 Flash electrical specifications

This section describes the electrical characteristics of the flash memory module.



3.4.1.1 Flash timing specifications — program and erase

The following specifications represent the amount of time the internal charge pumps are active and do not include command overhead.

Table 21. NVM program/erase timing specifications

| Symbol | Description | Min. | Тур. | Max. | Unit | Notes |
|---------------------------|--|------|------|------|------|-------|
| t _{hvpgm4} | Longword Program high-voltage time | _ | 7.5 | 18 | μs | _ |
| t _{hversscr} | Sector Erase high-voltage time | _ | 13 | 113 | ms | 1 |
| t _{hversblk128k} | Erase Block high-voltage time for 128 KB | _ | 52 | 452 | ms | 1 |
| t _{hversall} | Erase All high-voltage time | _ | 52 | 452 | ms | 1 |

^{1.} Maximum time based on expectations at cycling end-of-life.

3.4.1.2 Flash timing specifications — commands Table 22. Flash command timing specifications

| Symbol | Description | Min. | Тур. | Max. | Unit | Notes |
|-------------------------|---|------|------|------|------|-------|
| | Read 1s Block execution time | | | | | _ |
| t _{rd1blk128k} | 128 KB program flash | _ | _ | 1.7 | ms | |
| t _{rd1sec1k} | Read 1s Section execution time (flash sector) | _ | _ | 60 | μs | 1 |
| t _{pgmchk} | Program Check execution time | _ | _ | 45 | μs | 1 |
| t _{rdrsrc} | Read Resource execution time | _ | _ | 30 | μs | 1 |
| t _{pgm4} | Program Longword execution time | _ | 65 | 145 | μs | _ |
| | Erase Flash Block execution time | | | | | 2 |
| t _{ersblk128k} | 128 KB program flash | _ | 88 | 600 | ms | |
| t _{ersscr} | Erase Flash Sector execution time | _ | 14 | 114 | ms | 2 |
| t _{rd1all} | Read 1s All Blocks execution time | _ | _ | 1.8 | ms | _ |
| t _{rdonce} | Read Once execution time | _ | _ | 25 | μs | 1 |
| t _{pgmonce} | Program Once execution time | _ | 65 | _ | μs | _ |
| t _{ersall} | Erase All Blocks execution time | _ | 175 | 1300 | ms | 2 |
| t _{vfykey} | Verify Backdoor Access Key execution time | _ | _ | 30 | μs | 1 |

^{1.} Assumes 25 MHz flash clock frequency.

^{2.} Maximum times for erase parameters based on expectations at cycling end-of-life.



3.4.1.3 Flash high voltage current behaviors Table 23. Flash high voltage current behaviors

| Symbol | Description | Min. | Тур. | Max. | Unit |
|---------------------|---|------|------|------|------|
| I _{DD_PGM} | Average current adder during high voltage flash programming operation | _ | 2.5 | 6.0 | mA |
| I _{DD_ERS} | Average current adder during high voltage flash erase operation | _ | 1.5 | 4.0 | mA |

3.4.1.4 Reliability specifications

Table 24. NVM reliability specifications

| Symbol | Description | Min. | Typ. ¹ | Max. | Unit | Notes |
|-------------------------|--|------|-------------------|------|--------|-------|
| Program Flash | | | | | | |
| t _{nvmretp10k} | Data retention after up to 10 K cycles | 5 | 50 | _ | years | _ |
| t _{nvmretp1k} | Data retention after up to 1 K cycles | 20 | 100 | _ | years | _ |
| n _{nvmcycp} | Cycling endurance | 10 K | 50 K | _ | cycles | 2 |

Typical data retention values are based on measured response accelerated at high temperature and derated to a
constant 25 °C use profile. Engineering Bulletin EB618 does not apply to this technology. Typical endurance defined in
Engineering Bulletin EB619.

3.5 Security and integrity modules

There are no specifications necessary for the device's security and integrity modules.

3.6 Analog

3.6.1 ADC electrical specifications

The 16-bit accuracy specifications listed in Table 25 and Table 26 are achievable on the differential pins ADCx_DP0, ADCx_DM0.

All other ADC channels meet the 13-bit differential/12-bit single-ended accuracy specifications.

^{2.} Cycling endurance represents number of program/erase cycles at -40 °C \leq T_i \leq 125 °C.



3.6.1.1 16-bit ADC operating conditions Table 25. 16-bit ADC operating conditions

| Symbol | Description | Conditions | Min. | Typ. ¹ | Max. | Unit | Notes |
|-------------------|--------------------------------|--|------------------|-------------------|------------------|------|-------|
| V_{DDA} | Supply voltage | Absolute | 1.71 | _ | 3.6 | V | _ |
| ΔV_{DDA} | Supply voltage | Delta to V _{DD} (V _{DD} – V _{DDA}) | -100 | 0 | +100 | mV | 2 |
| ΔV_{SSA} | Ground voltage | Delta to V _{SS} (V _{SS} – V _{SSA}) | -100 | 0 | +100 | mV | 2 |
| V _{REFH} | ADC reference voltage high | | 1.13 | V_{DDA} | V_{DDA} | V | |
| V _{REFL} | ADC reference voltage low | | V _{SSA} | V _{SSA} | V _{SSA} | V | |
| V _{ADIN} | Input voltage | 16-bit differential mode | VREFL | _ | 31/32 * VREFH | V | _ |
| | | All other modes | VREFL | _ | VREFH | | |
| C _{ADIN} | Input | 16-bit mode | _ | 8 | 10 | pF | _ |
| | capacitance | 8-bit / 10-bit / 12-bit modes | _ | 4 | 5 | | |
| R _{ADIN} | Input series resistance | | _ | 2 | 5 | kΩ | _ |
| R _{AS} | Analog source | 13-bit / 12-bit modes | | | | | 3 |
| | resistance (external) | f _{ADCK} < 4 MHz | _ | _ | 5 | kΩ | |
| f _{ADCK} | ADC conversion clock frequency | ≤ 13-bit mode | 1.0 | _ | 18.0 | MHz | 4 |
| f _{ADCK} | ADC conversion clock frequency | 16-bit mode | 2.0 | _ | 12.0 | MHz | 4 |
| C _{rate} | ADC conversion | ≤ 13-bit modes | | | | | 5 |
| | rate | No ADC hardware averaging | 20.000 | _ | 818.330 | Ksps | |
| | | Continuous conversions enabled, subsequent conversion time | | | | | |
| C _{rate} | ADC conversion | 16-bit mode | | | | | 5 |
| | rate | No ADC hardware averaging | 37.037 | _ | 461.467 | Ksps | |
| | | Continuous conversions enabled, subsequent conversion time | | | | | |

^{1.} Typical values assume $V_{DDA} = 3.0 \text{ V}$, Temp = 25 °C, $f_{ADCK} = 1.0 \text{ MHz}$, unless otherwise stated. Typical values are for reference only, and are not tested in production.

^{2.} DC potential difference.

^{3.} This resistance is external to MCU. To achieve the best results, the analog source resistance must be kept as low as possible. The results in this data sheet were derived from a system that had < 8 Ω analog source resistance. The R_{AS}/C_{AS} time constant should be kept to < 1 ns.

^{4.} To use the maximum ADC conversion clock frequency, CFG2[ADHSC] must be set and CFG1[ADLPC] must be clear.

^{5.} For guidelines and examples of conversion rate calculation, download the ADC calculator tool.



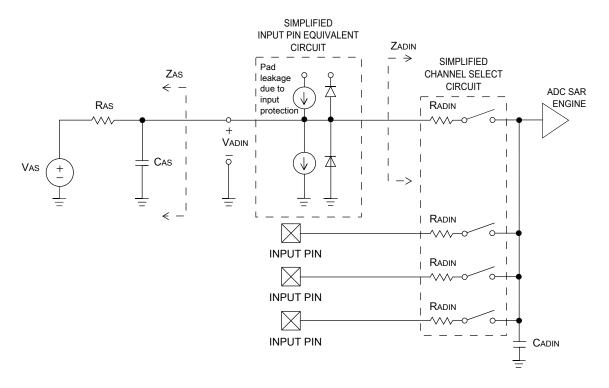


Figure 7. ADC input impedance equivalency diagram

3.6.1.2 16-bit ADC electrical characteristics

Table 26. 16-bit ADC characteristics ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SSA}$)

| Symbol | Description | Conditions ¹ | Min. | Typ. ² | Max. | Unit | Notes |
|----------------------|--------------------------------|-----------------------------|--------------|-------------------|-----------------|------------------|----------------------|
| I _{DDA_ADC} | Supply current | | 0.215 | _ | 1.7 | mA | 3 |
| | ADC | • ADLPC = 1, ADHSC = | 1.2 | 2.4 | 3.9 | MHz | t _{ADACK} = |
| | asynchronous clock source | 0 | 2.4 | 4.0 | 6.1 | MHz | 1/f _{ADACK} |
| | Clock Source | • ADLPC = 1, ADHSC = 1 | 3.0 | 5.2 | 7.3 | MHz | |
| f _{ADACK} | | • ADLPC = 0, ADHSC = 0 | 4.4 | 6.2 | 9.5 | MHz | |
| | | • ADLPC = 0, ADHSC = 1 | | | | | |
| | Sample Time | See Reference Manual chapte | r for sample | times | | | |
| TUE | Total unadjusted | 12-bit modes | _ | ±4 | ±6.8 | LSB ⁴ | 5 |
| | error | • <12-bit modes | _ | ±1.4 | ±2.1 | | |
| DNL | Differential non- linearity | 12-bit modes | _ | ±0.7 | -1.1 to +1.9 | LSB ⁴ | 5 |
| | , | • <12-bit modes | _ | ±0.2 | -0.3 to 0.5 | | |



Table 26. 16-bit ADC characteristics ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SSA}$) (continued)

| Symbol | Description | Conditions ¹ | Min. | Typ. ² | Max. | Unit | Notes |
|---------------------|----------------------------------|---|------|------------------------|-----------------|--|---|
| INL | Integral non- linearity | 12-bit modes | _ | ±1.0 | -2.7 to +1.9 | LSB ⁴ | 5 |
| | | • <12-bit modes | _ | ±0.5 | -0.7 to | | |
| | | | | | +0.5 | | |
| E_FS | E _{FS} Full-scale error | 12-bit modes | _ | -4 | -5.4 | LSB ⁴ | V _{ADIN} = |
| | | <12-bit modes | _ | -1.4 | -1.8 | | V _{DDA} ⁵ |
| E_Q | Quantization | 16-bit modes | _ | -1 to 0 | _ | LSB ⁴ | |
| | error | • ≤13-bit modes | _ | _ | ±0.5 | | |
| ENOB | Effective number of bits | 16-bit differential mode | 12.8 | 14.5 | _ | bits | 6 |
| | Of Dits | • Avg = 32 | 11.9 | 13.8 | _ | bits | |
| | | • Avg = 4 | | | | | |
| | | 40.1% | 12.2 | 13.9 | _ | bits | |
| | | 16-bit single-ended mode | 11.4 | 13.1 | _ | bits | |
| | | • Avg = 32 | | | | | |
| | | • Avg = 4 | | | | | |
| SINAD | Signal-to-noise plus distortion | See ENOB | 6.02 | 2 × ENOB + | 1.76 | dB | |
| THD | Total harmonic | 16-bit differential mode | _ | -94 | _ | dB | 7 |
| | distortion | • Avg = 32 | | 0.5 | | -ID | |
| | | 40 leit aim als souds dones de | _ | -85 | _ | dB | |
| | | 16-bit single-ended mode | | | | | |
| | | • Avg = 32 | | | | | |
| SFDR | Spurious free | 16-bit differential mode | 82 | 95 | _ | dB | 7 |
| | dynamic range | • Avg = 32 | 70 | | | l In | |
| | | 10 hit simple anded made | 78 | 90 | _ | dB | |
| | | 16-bit single-ended mode | | | | | |
| | | • Avg = 32 | | | | | |
| E _{IL} | Input leakage error | | | $I_{In} \times R_{AS}$ | | mV | I _{In} = leakage current |
| | | | | | | (refer to the MCU's voltage and current operating | |
| | - | A | | 4.00 | 4.00 | 1100 | ratings) |
| | Temp sensor slope | Across the full temperature range of the device | 1.55 | 1.62 | 1.69 | mV/°C | 8 |
| V _{TEMP25} | Temp sensor voltage | 25 °C | 706 | 716 | 726 | mV | 8 |



Peripheral operating requirements and behaviors

- 1. All accuracy numbers assume the ADC is calibrated with $V_{REFH} = V_{DDA}$
- Typical values assume V_{DDA} = 3.0 V, Temp = 25 °C, f_{ADCK} = 2.0 MHz unless otherwise stated. Typical values are for reference only and are not tested in production.
- The ADC supply current depends on the ADC conversion clock speed, conversion rate and ADC_CFG1[ADLPC] (low power). For lowest power operation, ADC_CFG1[ADLPC] must be set, the ADC_CFG2[ADHSC] bit must be clear with 1 MHz ADC conversion clock speed.
- 4. $1 LSB = (V_{REFH} V_{REFL})/2^{N}$
- 5. ADC conversion clock < 16 MHz, Max hardware averaging (AVGE = %1, AVGS = %11)
- 6. Input data is 100 Hz sine wave. ADC conversion clock < 12 MHz.
- 7. Input data is 1 kHz sine wave. ADC conversion clock < 12 MHz.
- 8. ADC conversion clock < 3 MHz

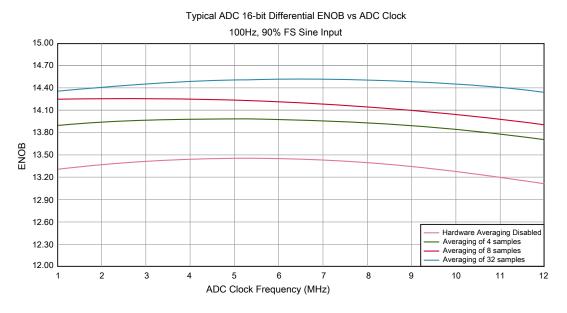


Figure 8. Typical ENOB vs. ADC_CLK for 16-bit differential mode

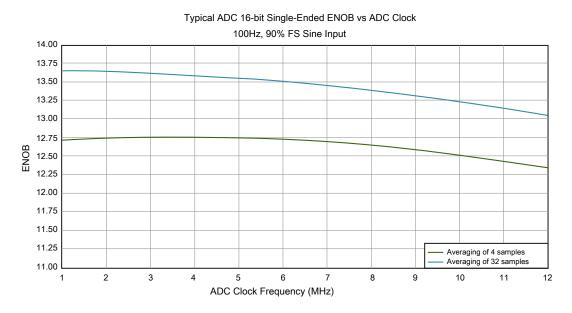


Figure 9. Typical ENOB vs. ADC_CLK for 16-bit single-ended mode



3.6.2 CMP and 6-bit DAC electrical specifications

Table 27. Comparator and 6-bit DAC electrical specifications

| Symbol | Description | Min. | Тур. | Max. | Unit |
|--------------------|---|-----------------------|------|----------|------------------|
| V_{DD} | Supply voltage | 1.71 | _ | 3.6 | V |
| I _{DDHS} | Supply current, High-speed mode (EN=1, PMODE=1) | _ | _ | 200 | μА |
| I _{DDLS} | Supply current, low-speed mode (EN=1, PMODE=0) | _ | _ | 20 | μΑ |
| V _{AIN} | Analog input voltage | V _{SS} - 0.3 | _ | V_{DD} | V |
| V _{AIO} | Analog input offset voltage | _ | _ | 20 | mV |
| V _H | Analog comparator hysteresis ¹ | | | | |
| | • CR0[HYSTCTR] = 00 | _ | 5 | _ | mV |
| | • CR0[HYSTCTR] = 01 | _ | 10 | _ | mV |
| | • CR0[HYSTCTR] = 10 | _ | 20 | _ | mV |
| | • CR0[HYSTCTR] = 11 | _ | 30 | _ | mV |
| V _{CMPOh} | Output high | V _{DD} – 0.5 | _ | _ | V |
| V _{CMPOI} | Output low | _ | _ | 0.5 | V |
| t _{DHS} | Propagation delay, high-speed mode (EN=1, PMODE=1) | 20 | 50 | 200 | ns |
| t _{DLS} | Propagation delay, low-speed mode (EN=1, PMODE=0) | 80 | 250 | 600 | ns |
| | Analog comparator initialization delay ² | _ | _ | 40 | μs |
| I _{DAC6b} | 6-bit DAC current adder (enabled) | _ | 7 | _ | μΑ |
| INL | 6-bit DAC integral non-linearity | -0.5 | _ | 0.5 | LSB ³ |
| DNL | 6-bit DAC differential non-linearity | -0.3 | _ | 0.3 | LSB |

^{1.} Typical hysteresis is measured with input voltage range limited to 0.6 to V_{DD} –0.6 V.

^{2.} Comparator initialization delay is defined as the time between software writes to change control inputs (Writes to CMP_DACCR[DACEN], CMP_DACCR[VRSEL], CMP_DACCR[VOSEL], CMP_MUXCR[PSEL], and CMP_MUXCR[MSEL]) and the comparator output settling to a stable level.

^{3. 1} LSB = V_{reference}/64



Peripheral operating requirements and behaviors

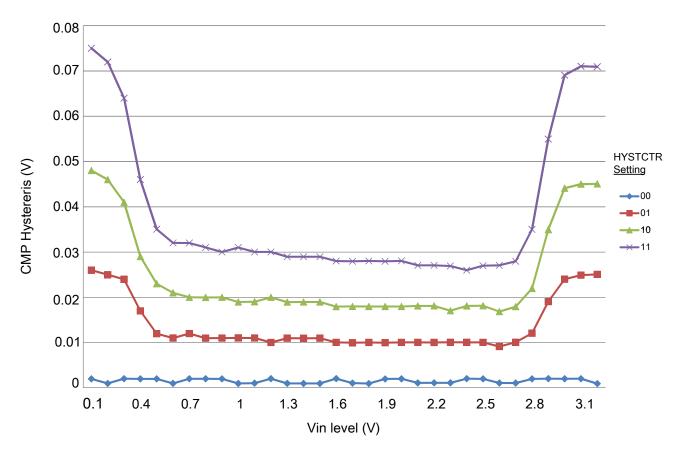


Figure 10. Typical hysteresis vs. Vin level (VDD = 3.3 V, PMODE = 0)



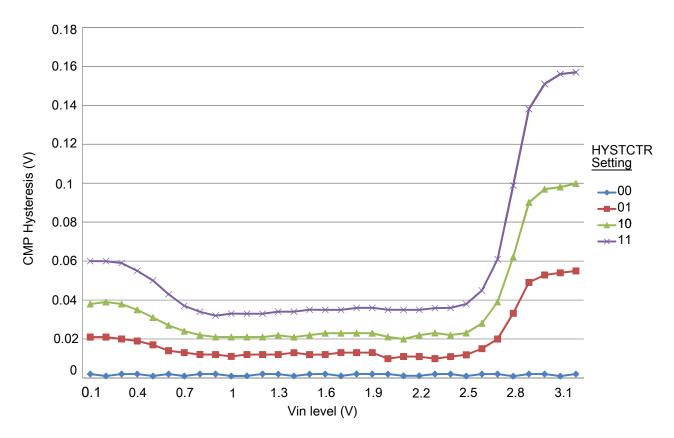


Figure 11. Typical hysteresis vs. Vin level (VDD = 3.3 V, PMODE = 1)

3.6.3 12-bit DAC electrical characteristics

3.6.3.1 12-bit DAC operating requirements Table 28. 12-bit DAC operating requirements

| Symbol | Desciption | Min. | Max. | Unit | Notes |
|-------------------|-------------------------|------|------|------|-------|
| V_{DDA} | Supply voltage | 1.71 | 3.6 | V | |
| V _{DACR} | Reference voltage | 1.13 | 3.6 | V | 1 |
| C _L | Output load capacitance | _ | 100 | pF | 2 |
| IL | Output load current | 1 | 1 | mA | |

- 1. The DAC reference can be selected to be V_{DDA} or V_{REFH} .
- 2. A small load capacitance (47 pF) can improve the bandwidth performance of the DAC.



3.6.3.2 12-bit DAC operating behaviors Table 29. 12-bit DAC operating behaviors

| Symbol | Description | Min. | Тур. | Max. | Unit | Notes |
|-----------------------|--|---------------------------|----------|------------|--------|-------|
| I _{DDA_DACL} | Supply current — low-power mode | _ | _ | 250 | μΑ | |
| I _{DDA_DACH} | Supply current — high-speed mode | _ | _ | 900 | μΑ | |
| t _{DACLP} | Full-scale settling time (0x080 to 0xF7F) — low-power mode | _ | 100 | 200 | μs | 1 |
| t _{DACHP} | Full-scale settling time (0x080 to 0xF7F) — high-power mode | | 15 | 30 | μs | 1 |
| t _{CCDACLP} | Code-to-code settling time (0xBF8 to 0xC08) — low-power mode and high-speed mode | _ | 0.7 | 1 | μs | 1 |
| V _{dacoutl} | DAC output voltage range low — high- speed mode, no load, DAC set to 0x000 | _ | _ | 100 | mV | |
| V _{dacouth} | DAC output voltage range high — high- speed mode, no load, DAC set to 0xFFF | V _{DACR} -100 | _ | V_{DACR} | mV | |
| INL | Integral non-linearity error — high speed mode | _ | _ | ±8 | LSB | 2 |
| DNL | Differential non-linearity error — V _{DACR} > 2 V | _ | _ | ±1 | LSB | 3 |
| DNL | Differential non-linearity error — V _{DACR} = VREF_OUT | _ | _ | ±1 | LSB | 4 |
| V _{OFFSET} | Offset error | _ | ±0.4 | ±0.8 | %FSR | 5 |
| E _G | Gain error | _ | ±0.1 | ±0.6 | %FSR | 5 |
| PSRR | Power supply rejection ratio, V _{DDA} ≥ 2.4 V | 60 | _ | 90 | dB | |
| T _{CO} | Temperature coefficient offset voltage | _ | 3.7 | _ | μV/C | 6 |
| T_GE | Temperature coefficient gain error | _ | 0.000421 | _ | %FSR/C | |
| Rop | Output resistance (load = $3 \text{ k}\Omega$) | 1 | | 250 | Ω | |
| SR | Slew rate -80h→ F7Fh→ 80h | | | | V/µs | |
| | High power (SP _{HP}) | 1.2 | 1.7 | _ | | |
| | • Low power (SP _{LP}) | 0.05 | 0.12 | _ | | |
| BW | 3dB bandwidth | | | | kHz | |
| | High power (SP _{HP}) | 550 | _ | _ | | |
| | • Low power (SP _{LP}) | 40 | - | _ | | |

- 1. Settling within ±1 LSB
- 2. The INL is measured for 0 + 100 mV to V_{DACR} –100 mV
- 3. The DNL is measured for 0 + 100 mV to V_{DACR} –100 mV
- 4. The DNL is measured for 0 + 100 mV to V_{DACR} -100 mV with V_{DDA} > 2.4 V 5. Calculated by a best fit curve from V_{SS} + 100 mV to V_{DACR} 100 mV
- 6. $V_{DDA} = 3.0 \text{ V}$, reference select set for V_{DDA} (DACx_CO:DACRFS = 1), high power mode (DACx_CO:LPEN = 0), DAC set to 0x800, temperature range is across the full range of the device



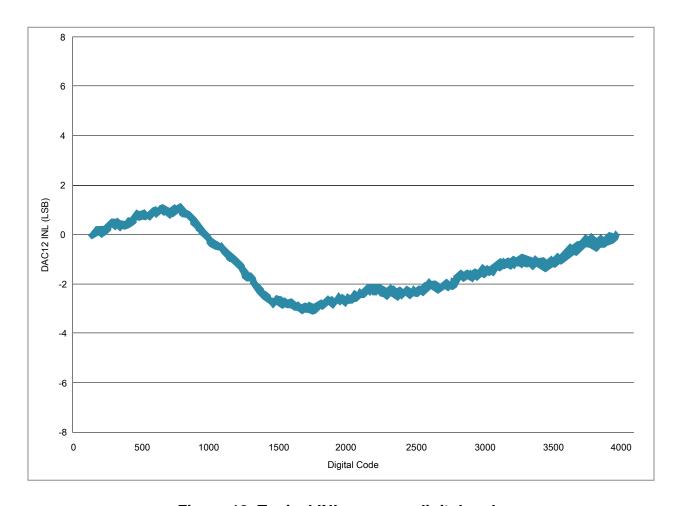


Figure 12. Typical INL error vs. digital code



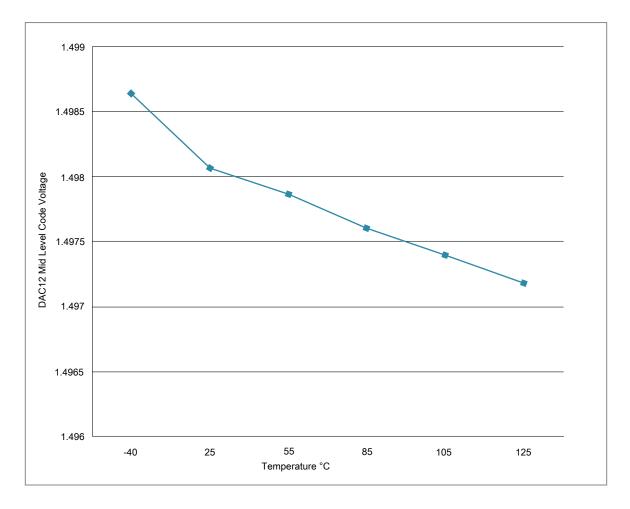


Figure 13. Offset at half scale vs. temperature

3.7 Timers

See General switching specifications.

3.8 Communication interfaces

3.8.1 USB electrical specifications

The USB electricals for the USB On-the-Go module conform to the standards documented by the Universal Serial Bus Implementers Forum. For the most up-to-date standards, visit **usb.org**.



NOTE

The MCGPLLCLK meets the USB jitter specifications for certification with the use of an external clock/crystal for both Device and Host modes.

The MCGFLLCLK does not meet the USB jitter specifications for certification.

3.8.2 USB VREG electrical specifications Table 30. USB VREG electrical specifications

| Symbol | Description | Min. | Typ. ¹ | Max. | Unit | Notes |
|-----------------------|---|--------|-------------------|------|----------|-------|
| VREGIN | Input supply voltage | 2.7 | _ | 5.5 | V | |
| I _{DDon} | Quiescent current — Run mode, load current equal zero, input supply (VREGIN) > 3.6 V | _ | 125 | 186 | μΑ | |
| I _{DDstby} | Quiescent current — Standby mode, load current equal zero | _ | 1.1 | 10 | μΑ | |
| I _{DDoff} | Quiescent current — Shutdown mode • VREGIN = 5.0 V and temperature=25 °C • Across operating voltage and temperature | _ _ | 650 — | 4 | nA μA | |
| I _{LOADrun} | Maximum load current — Run mode | _ | _ | 120 | mA | |
| I _{LOADstby} | Maximum load current — Standby mode | _ | _ | 1 | mA | |
| V _{Reg33out} | Regulator output voltage — Input supply (VREGIN) > 3.6 V | | | | | |
| | Run mode | 3 | 3.3 | 3.6 | V | |
| | Standby mode | 2.1 | 2.8 | 3.6 | V | |
| V _{Reg33out} | Regulator output voltage — Input supply (VREGIN) < 3.6 V, pass-through mode | 2.1 | _ | 3.6 | V | 2 |
| C _{OUT} | External output capacitor | 1.76 | 2.2 | 8.16 | μF | |
| ESR | External output capacitor equivalent series resistance | 1 | _ | 100 | mΩ | |
| I _{LIM} | Short circuit current | _ | 290 | _ | mA | |

^{1.} Typical values assume VREGIN = 5.0 V, Temp = 25 °C unless otherwise stated.

^{2.} Operating in pass-through mode: regulator output voltage equal to the input voltage minus a drop proportional to I_{Load}.



3.8.3 SPI switching specifications

The Serial Peripheral Interface (SPI) provides a synchronous serial bus with master and slave operations. Many of the transfer attributes are programmable. The following tables provide timing characteristics for classic SPI timing modes. See the SPI chapter of the chip's Reference Manual for information about the modified transfer formats used for communicating with slower peripheral devices.

All timing is shown with respect to $20\%~V_{DD}$ and $80\%~V_{DD}$ thresholds, unless noted, as well as input signal transitions of 3 ns and a 30 pF maximum load on all SPI pins.

Table 31. SPI master mode timing on slew rate disabled pads

| Num. | Symbol | Description | Min. | Max. | Unit | Note |
|------|---------------------|--------------------------------|---------------------------|--------------------------|--------------------|------|
| 1 | f _{op} | Frequency of operation | f _{periph} /2048 | f _{periph} /2 | Hz | 1 |
| 2 | t _{SPSCK} | SPSCK period | 2 x t _{periph} | 2048 x | ns | 2 |
| | | | | t _{periph} | | |
| 3 | t _{Lead} | Enable lead time | 1/2 | _ | t _{SPSCK} | _ |
| 4 | t _{Lag} | Enable lag time | 1/2 | _ | t _{SPSCK} | _ |
| 5 | t _{WSPSCK} | Clock (SPSCK) high or low time | t _{periph} - 30 | 1024 x | ns | _ |
| | | | | t _{periph} | | |
| 6 | t _{SU} | Data setup time (inputs) | 18 | _ | ns | _ |
| 7 | t _{HI} | Data hold time (inputs) | 0 | _ | ns | _ |
| 8 | t _v | Data valid (after SPSCK edge) | _ | 15 | ns | _ |
| 9 | t _{HO} | Data hold time (outputs) | 0 | _ | ns | _ |
| 10 | t _{RI} | Rise time input | _ | t _{periph} - 25 | ns | _ |
| | t _{Fl} | Fall time input | | | | |
| 11 | t _{RO} | Rise time output | _ | 25 | ns | _ |
| | t _{FO} | Fall time output | | | | |

^{1.} For SPI0 f_{periph} is the bus clock (f_{BUS}). For SPI1 f_{periph} is the system clock (f_{SYS}).

Table 32. SPI master mode timing on slew rate enabled pads

| Num. | Symbol | Description | Min. | Max. | Unit | Note |
|------|--------------------|--------------------------------|---------------------------|-------------------------------|--------------------|------|
| 1 | f _{op} | Frequency of operation | f _{periph} /2048 | f _{periph} /2 | Hz | 1 |
| 2 | t _{SPSCK} | SPSCK period | 2 x t _{periph} | 2048 x t _{periph} | ns | 2 |
| 3 | t _{Lead} | Enable lead time | 1/2 | _ | t _{SPSCK} | _ |
| 4 | t _{Lag} | Enable lag time | 1/2 | _ | t _{SPSCK} | _ |
| 5 | twspsck | Clock (SPSCK) high or low time | t _{periph} - 30 | 1024 x t _{periph} | ns | _ |
| 6 | t _{SU} | Data setup time (inputs) | 96 | _ | ns | _ |
| 7 | t _{HI} | Data hold time (inputs) | 0 | _ | ns | _ |

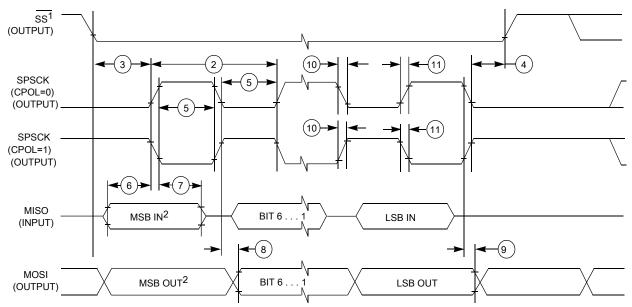
^{2.} $t_{periph} = 1/f_{periph}$



| Table 32. | SPI master mode timing | on slew rate enabled | pads (continued) |
|-----------|------------------------|----------------------|------------------|
|-----------|------------------------|----------------------|------------------|

| Num. | Symbol | Description | Min. | Max. | Unit | Note |
|------|-----------------|-------------------------------|------|--------------------------|------|------|
| 8 | t _v | Data valid (after SPSCK edge) | _ | 52 | ns | _ |
| 9 | t _{HO} | Data hold time (outputs) | 0 | _ | ns | _ |
| 10 | t _{RI} | Rise time input | _ | t _{periph} - 25 | ns | _ |
| | t _{FI} | Fall time input | | | | |
| 11 | t _{RO} | Rise time output | _ | 36 | ns | _ |
| | t _{FO} | Fall time output | | | | |

- 1. For SPI0 f_{periph} is the bus clock (f_{BUS}). For SPI1 f_{periph} is the system clock (f_{SYS}).
- 2. $t_{periph} = 1/f_{periph}$

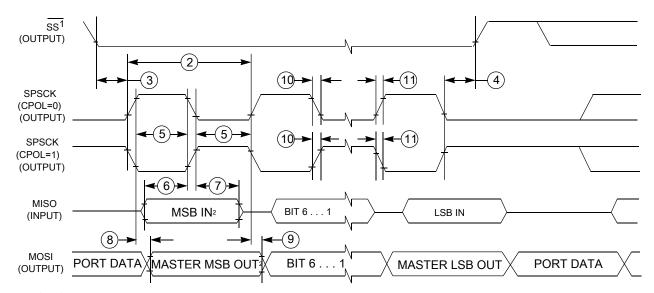


- 1. If configured as an output.
 2. LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

Figure 14. SPI master mode timing (CPHA = 0)



Peripheral operating requirements and behaviors



^{1.}If configured as output

Figure 15. SPI master mode timing (CPHA = 1)

Table 33. SPI slave mode timing on slew rate disabled pads

| Num. | Symbol | Description | Min. | Max. | Unit | Note |
|------|---------------------|--------------------------------|--------------------------|--------------------------|---------------------|------|
| 1 | f _{op} | Frequency of operation | 0 | f _{periph} /4 | Hz | 1 |
| 2 | t _{SPSCK} | SPSCK period | 4 x t _{periph} | _ | ns | 2 |
| 3 | t _{Lead} | Enable lead time | 1 | _ | t _{periph} | _ |
| 4 | t _{Lag} | Enable lag time | 1 | _ | t _{periph} | _ |
| 5 | t _{WSPSCK} | Clock (SPSCK) high or low time | t _{periph} - 30 | _ | ns | _ |
| 6 | t _{SU} | Data setup time (inputs) | 2.5 | _ | ns | _ |
| 7 | t _{HI} | Data hold time (inputs) | 3.5 | _ | ns | _ |
| 8 | t _a | Slave access time | _ | t _{periph} | ns | 3 |
| 9 | t _{dis} | Slave MISO disable time | _ | t _{periph} | ns | 4 |
| 10 | t _v | Data valid (after SPSCK edge) | _ | 31 | ns | _ |
| 11 | t _{HO} | Data hold time (outputs) | 0 | _ | ns | _ |
| 12 | t _{RI} | Rise time input | _ | t _{periph} - 25 | ns | _ |
| | t _{Fl} | Fall time input |] | | | |
| 13 | t _{RO} | Rise time output | _ | 25 | ns | _ |
| | t _{FO} | Fall time output | | | | |

^{1.} For SPI0 f_{periph} is the bus clock (f_{BUS}). For SPI1 f_{periph} is the system clock (f_{SYS}).

^{2.} LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

^{2.} $t_{periph} = 1/f_{periph}$

^{3.} Time to data active from high-impedance state

^{4.} Hold time to high-impedance state



| Num. | Symbol | Description | Min. | Max. | Unit | Note |
|------|---------------------|--------------------------------|--------------------------|--------------------------|---------------------|------|
| 1 | f _{op} | Frequency of operation | 0 | f _{periph} /4 | Hz | 1 |
| 2 | t _{SPSCK} | SPSCK period | 4 x t _{periph} | _ | ns | 2 |
| 3 | t _{Lead} | Enable lead time | 1 | _ | t _{periph} | _ |
| 4 | t _{Lag} | Enable lag time | 1 | _ | t _{periph} | _ |
| 5 | t _{WSPSCK} | Clock (SPSCK) high or low time | t _{periph} - 30 | _ | ns | _ |
| 6 | t _{SU} | Data setup time (inputs) | 2 | _ | ns | _ |
| 7 | t _{HI} | Data hold time (inputs) | 7 | _ | ns | _ |
| 8 | t _a | Slave access time | _ | t _{periph} | ns | 3 |
| 9 | t _{dis} | Slave MISO disable time | _ | t _{periph} | ns | 4 |
| 10 | t _v | Data valid (after SPSCK edge) | _ | 122 | ns | _ |
| 11 | t _{HO} | Data hold time (outputs) | 0 | _ | ns | _ |
| 12 | t _{RI} | Rise time input | _ | t _{periph} - 25 | ns | _ |
| | t _{FI} | Fall time input | | | | |
| 13 | t _{RO} | Rise time output | | 36 | ns | _ |

Table 34. SPI slave mode timing on slew rate enabled pads

1. For SPI0 f_{periph} is the bus clock (f_{BUS}). For SPI1 f_{periph} is the system clock (f_{SYS}).

Fall time output

- 2. $t_{periph} = 1/f_{periph}$
- 3. Time to data active from high-impedance state
- 4. Hold time to high-impedance state

 t_{FO}

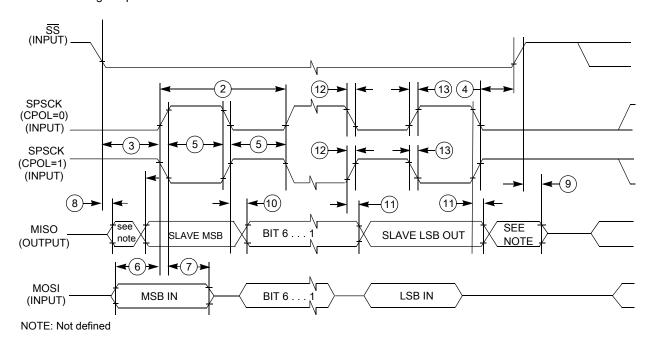


Figure 16. SPI slave mode timing (CPHA = 0)



Peripheral operating requirements and behaviors

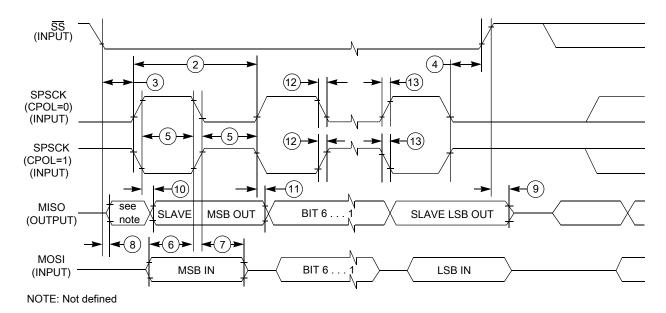


Figure 17. SPI slave mode timing (CPHA = 1)

3.8.4 Inter-Integrated Circuit Interface (I2C) timing Table 35. I2C timing

| Characteristic | Symbol | Standa | rd Mode | Fast | Mode | Unit |
|--|-----------------------|------------------|-------------------|------------------------------------|------------------|------|
| | | Minimum | Maximum | Minimum | Maximum | |
| SCL Clock Frequency | f _{SCL} | 0 | 100 | 0 | 400 ¹ | kHz |
| Hold time (repeated) START condition. After this period, the first clock pulse is generated. | t _{HD} ; STA | 4 | _ | 0.6 | _ | μs |
| LOW period of the SCL clock | t _{LOW} | 4.7 | _ | 1.3 | _ | μs |
| HIGH period of the SCL clock | t _{HIGH} | 4 | _ | 0.6 | _ | μs |
| Set-up time for a repeated START condition | t _{SU} ; STA | 4.7 | _ | 0.6 | _ | μs |
| Data hold time for I ² C bus devices | t _{HD} ; DAT | 0 ² | 3.45 ³ | 04 | 0.9 ² | μs |
| Data set-up time | t _{SU} ; DAT | 250 ⁵ | _ | 100 ³ , ⁶ | _ | ns |
| Rise time of SDA and SCL signals | t _r | _ | 1000 | 20 +0.1C _b ⁷ | 300 | ns |
| Fall time of SDA and SCL signals | t _f | _ | 300 | 20 +0.1C _b ⁶ | 300 | ns |
| Set-up time for STOP condition | t _{SU} ; STO | 4 | _ | 0.6 | _ | μs |
| Bus free time between STOP and START condition | t _{BUF} | 4.7 | _ | 1.3 | _ | μs |
| Pulse width of spikes that must be suppressed by the input filter | t _{SP} | N/A | N/A | 0 | 50 | ns |

^{1.} The maximum SCL Clock Frequency in Fast mode with maximum bus loading can only achieved when using the High drive pins (see Voltage and current operating behaviors) or when using the Normal drive pins and VDD ≥ 2.7 V



- The master mode I²C deasserts ACK of an address byte simultaneously with the falling edge of SCL. If no slaves
 acknowledge this address byte, then a negative hold time can result, depending on the edge rates of the SDA and
 SCL lines.
- 3. The maximum tHD; DAT must be met only if the device does not stretch the LOW period (tLOW) of the SCL signal.
- 4. Input signal Slew = 10 ns and Output Load = 50 pF
- 5. Set-up time in slave-transmitter mode is 1 IPBus clock period, if the TX FIFO is empty.
- 6. A Fast mode I^2C bus device can be used in a Standard mode I^2C bus system, but the requirement $t_{SU; DAT} \ge 250$ ns must then be met. This is automatically the case if the device does not stretch the LOW period of the SCL signal. If such a device does stretch the LOW period of the SCL signal, then it must output the next data bit to the SDA line $t_{rmax} + t_{SU; DAT} = 1000 + 250 = 1250$ ns (according to the Standard mode I^2C bus specification) before the SCL line is released.
- 7. $C_b = \text{total capacitance of the one bus line in pF}$.

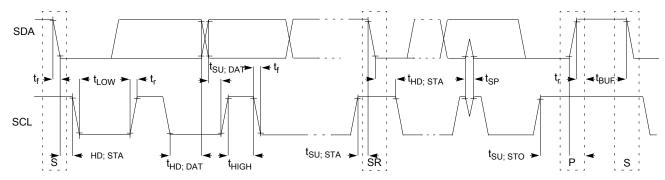


Figure 18. Timing definition for fast and standard mode devices on the I²C bus

3.8.5 **UART**

See General switching specifications.

3.8.6 I2S/SAI switching specifications

This section provides the AC timing for the I2S/SAI module in master mode (clocks are driven) and slave mode (clocks are input). All timing is given for noninverted serial clock polarity (TCR2[BCP] is 0, RCR2[BCP] is 0) and a noninverted frame sync (TCR4[FSP] is 0, RCR4[FSP] is 0). If the polarity of the clock and/or the frame sync have been inverted, all the timing remains valid by inverting the bit clock signal (BCLK) and/or the frame sync (FS) signal shown in the following figures.



3.8.6.1 Normal Run, Wait and Stop mode performance over the full operating voltage range

This section provides the operating performance over the full operating voltage for the device in Normal Run, Wait and Stop modes.

| Num. | Characteristic | Min. | Max. | Unit |
|------|---|------|------|-------------|
| | Operating voltage | 1.71 | 3.6 | V |
| S1 | I2S_MCLK cycle time | 40 | _ | ns |
| S2 | I2S_MCLK (as an input) pulse width high/low | 45% | 55% | MCLK period |
| S3 | I2S_TX_BCLK/I2S_RX_BCLK cycle time (output) | 80 | _ | ns |
| S4 | I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low | 45% | 55% | BCLK period |
| S5 | I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output valid | _ | 15.5 | ns |
| S6 | I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output invalid | 0 | _ | ns |
| S7 | I2S_TX_BCLK to I2S_TXD valid | _ | 19 | ns |
| S8 | I2S_TX_BCLK to I2S_TXD invalid | 0 | _ | ns |
| S9 | I2S_RXD/I2S_RX_FS input setup before I2S_RX_BCLK | 26 | _ | ns |
| S10 | I2S_RXD/I2S_RX_FS input hold after I2S_RX_BCLK | 0 | _ | ns |

Table 36. I2S/SAI master mode timing

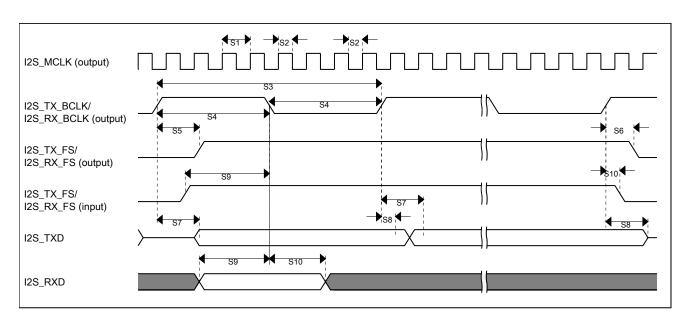


Figure 19. I2S/SAI timing — master modes



| Num. | Characteristic | Min. | Max. | Unit |
|------|--|------|------|-------------|
| | Operating voltage | 1.71 | 3.6 | V |
| S11 | I2S_TX_BCLK/I2S_RX_BCLK cycle time (input) | 80 | _ | ns |
| S12 | I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low (input) | 45% | 55% | MCLK period |
| S13 | I2S_TX_FS/I2S_RX_FS input setup before I2S_TX_BCLK/I2S_RX_BCLK | 10 | _ | ns |
| S14 | I2S_TX_FS/I2S_RX_FS input hold after I2S_TX_BCLK/I2S_RX_BCLK | 2 | _ | ns |
| S15 | I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output valid | _ | 33 | ns |
| S16 | I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output invalid | 0 | _ | ns |
| S17 | I2S_RXD setup before I2S_RX_BCLK | 10 | _ | ns |
| S18 | I2S_RXD hold after I2S_RX_BCLK | 2 | _ | ns |
| S19 | I2S_TX_FS input assertion to I2S_TXD output valid1 | _ | 28 | ns |

Table 37. I2S/SAI slave mode timing

1. Applies to first bit in each frame and only if the TCR4[FSE] bit is clear

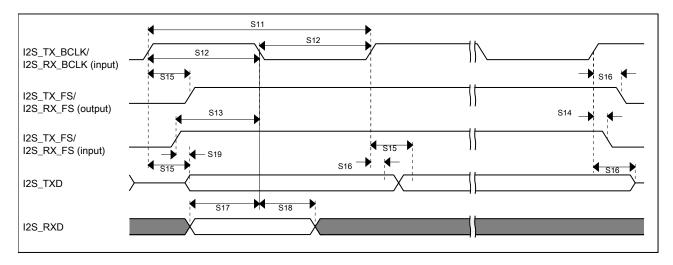


Figure 20. I2S/SAI timing — slave modes

3.8.6.2 VLPR, VLPW, and VLPS mode performance over the full operating voltage range

This section provides the operating performance over the full operating voltage for the device in VLPR, VLPW, and VLPS modes.



Table 38. I2S/SAI master mode timing in VLPR, VLPW, and VLPS modes (full voltage range)

| Num. | Characteristic | Min. | Max. | Unit |
|------|---|------|------|-------------|
| | Operating voltage | 1.71 | 3.6 | V |
| S1 | I2S_MCLK cycle time | 62.5 | _ | ns |
| S2 | I2S_MCLK pulse width high/low | 45% | 55% | MCLK period |
| S3 | I2S_TX_BCLK/I2S_RX_BCLK cycle time (output) | 250 | _ | ns |
| S4 | I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low | 45% | 55% | BCLK period |
| S5 | I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output valid | _ | 45 | ns |
| S6 | I2S_TX_BCLK/I2S_RX_BCLK to I2S_TX_FS/ I2S_RX_FS output invalid | 0 | _ | ns |
| S7 | I2S_TX_BCLK to I2S_TXD valid | _ | 45 | ns |
| S8 | I2S_TX_BCLK to I2S_TXD invalid | 0 | _ | ns |
| S9 | I2S_RXD/I2S_RX_FS input setup before I2S_RX_BCLK | 75 | _ | ns |
| S10 | I2S_RXD/I2S_RX_FS input hold after I2S_RX_BCLK | 0 | _ | ns |

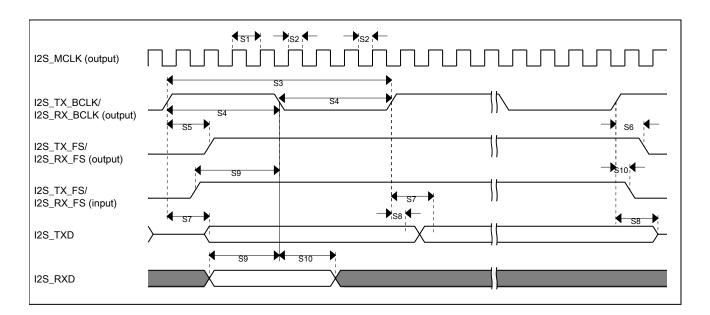


Figure 21. I2S/SAI timing — master modes

Table 39. I2S/SAI slave mode timing in VLPR, VLPW, and VLPS modes (full voltage range)

| Num. | Characteristic | Min. | Max. | Unit |
|------|--|------|------|------|
| | Operating voltage | 1.71 | 3.6 | V |
| S11 | I2S_TX_BCLK/I2S_RX_BCLK cycle time (input) | 250 | _ | ns |



Table 39. I2S/SAI slave mode timing in VLPR, VLPW, and VLPS modes (full voltage range) (continued)

| Num. | Characteristic | Min. | Max. | Unit |
|------|--|------|------|-------------|
| S12 | I2S_TX_BCLK/I2S_RX_BCLK pulse width high/low (input) | 45% | 55% | MCLK period |
| S13 | I2S_TX_FS/I2S_RX_FS input setup before I2S_TX_BCLK/I2S_RX_BCLK | 30 | _ | ns |
| S14 | I2S_TX_FS/I2S_RX_FS input hold after I2S_TX_BCLK/I2S_RX_BCLK | 2 | _ | ns |
| S15 | I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output valid | _ | 87 | ns |
| S16 | I2S_TX_BCLK to I2S_TXD/I2S_TX_FS output invalid | 0 | _ | ns |
| S17 | I2S_RXD setup before I2S_RX_BCLK | 30 | _ | ns |
| S18 | I2S_RXD hold after I2S_RX_BCLK | 2 | _ | ns |
| S19 | I2S_TX_FS input assertion to I2S_TXD output valid ¹ | _ | 72 | ns |

1. Applies to first bit in each frame and only if the TCR4[FSE] bit is clear

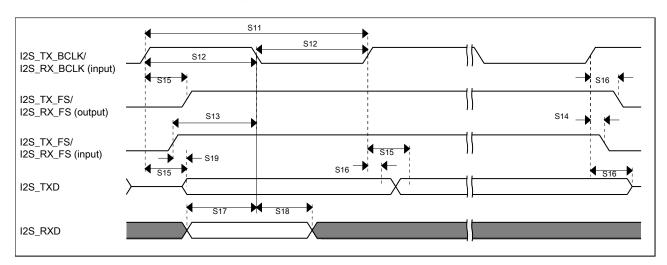


Figure 22. I2S/SAI timing — slave modes

3.9 Human-machine interfaces (HMI)

3.9.1 TSI electrical specifications

Table 40. TSI electrical specifications

| Symbol | Description | Min. | Тур. | Max. | Unit |
|----------|-------------------------------------|------|------|------|------|
| TSI_RUNF | Fixed power consumption in run mode | _ | 100 | _ | μΑ |



Table 40. TSI electrical specifications (continued)

| Symbol | Description | Min. | Тур. | Max. | Unit |
|-----------|--|------|------|------|------|
| TSI_RUNV | Variable power consumption in run mode (depends on oscillator's current selection) | 1.0 | _ | 128 | μА |
| TSI_EN | Power consumption in enable mode | _ | 100 | _ | μΑ |
| TSI_DIS | Power consumption in disable mode | _ | 1.2 | _ | μA |
| TSI_TEN | TSI analog enable time | _ | 66 | _ | μs |
| TSI_CREF | TSI reference capacitor | _ | 1.0 | _ | pF |
| TSI_DVOLT | Voltage variation of VP & VM around nominal values | 0.19 | _ | 1.03 | V |

3.9.2 LCD electrical characteristics

Table 41. LCD electricals

| Symbol | Description | Min. | Тур. | Max. | Unit | Notes |
|--------------------|---|------|------|-------|------|-------|
| f _{Frame} | LCD frame frequency | | | | | |
| | • GCR[FFR]=0 | 23.3 | _ | 73.1 | Hz | |
| | GCR[FFR]=1 | 46.6 | _ | 146.2 | Hz | |
| C _{LCD} | LCD charge pump capacitance — nominal value | _ | 100 | _ | nF | 1 |
| C _{BYLCD} | LCD bypass capacitance — nominal value | _ | 100 | _ | nF | 1 |
| C _{Glass} | LCD glass capacitance | _ | 2000 | 8000 | pF | 2 |
| V _{IREG} | V _{IREG} | | | | V | 3 |
| | • RVTRIM=0000 | _ | 0.91 | _ | | |
| | • RVTRIM=1000 | _ | 0.92 | _ | | |
| | • RVTRIM=0100 | _ | 0.93 | _ | | |
| | • RVTRIM=1100 | _ | 0.94 | _ | | |
| | • RVTRIM=0010 | _ | 0.96 | _ | | |
| | • RVTRIM=1010 | _ | 0.97 | _ | | |
| | • RVTRIM=0110 | _ | 0.98 | _ | | |
| | • RVTRIM=1110 | _ | 0.99 | _ | | |
| | • RVTRIM=0001 | _ | 1.01 | _ | | |
| | • RVTRIM=1001 | _ | 1.02 | _ | | |
| | • RVTRIM=0101 | _ | 1.03 | _ | | |
| | • RVTRIM=1101 | _ | 1.05 | _ | | |
| | • RVTRIM=0011 | _ | 1.06 | _ | | |
| | • RVTRIM=1011 | _ | 1.07 | _ | | |
| | | _ | 1.08 | _ | | |



| Symbol | Description | Min. | Тур. | Max. | Unit | Notes |
|--------------------|---|------|------|------------------------|---------------------|-------|
| | • RVTRIM=0111 | _ | 1.09 | _ | | |
| | • RVTRIM=1111 | | | | | |
| Δ_{RTRIM} | V _{IREG} TRIM resolution | _ | _ | 3.0 | % V _{IREG} | |
| I _{VIREG} | V _{IREG} current adder — RVEN = 1 | _ | 1 | _ | μΑ | 4 |
| I _{RBIAS} | RBIAS current adder | | | | | |
| | • LADJ = 10 or 11 — High load (LCD glass capacitance ≤ 8000 pF) | _ | 10 | _ | μΑ | |
| | • LADJ = 00 or 01 — Low load (LCD glass capacitance ≤ 2000 pF) | _ | 1 | _ | μΑ | |
| R _{RBIAS} | RBIAS resistor values | | | | | |
| | • LADJ = 10 or 11 — High load (LCD glass capacitance ≤ 8000 pF) | _ | 0.28 | _ | ΜΩ | |
| | • LADJ = 00 or 01 — Low load (LCD glass capacitance ≤ 2000 pF) | _ | 2.98 | _ | ΜΩ | |
| VLL1 | VLL1 voltage | _ | _ | V _{IREG} | V | 5 |
| VLL2 | VLL2 voltage | _ | _ | 2 x V _{IREG} | V | 5 |
| VLL3 | VLL3 voltage | _ | _ | 3 x V _{IREG} | V | 5 |
| VLL1 | VLL1 voltage | _ | _ | V _{DDA} / 3 | V | 6 |
| VLL2 | VLL2 voltage | _ | _ | V _{DDA} / 1.5 | V | 6 |
| VLL3 | VLL3 voltage | _ | _ | V_{DDA} | V | 6 |

- 1. The actual value used could vary with tolerance.
- 2. For highest glass capacitance values, LCD_GCR[LADJ] should be configured as specified in the LCD Controller chapter within the device's reference manual.
- 3. V_{IREG} maximum should never be externally driven to any level other than V_{DD} 0.15 V
- 4. 2000 pF load LCD, 32 Hz frame frequency
- VLL1, VLL2 and VLL3 are a function of V_{IREG} only when the regulator is enabled (GCR[RVEN]=1) and the charge pump is enabled (GCR[CPSEL]=1).
- 6. VLL1, VLL2 and VLL3 are a function of V_{DDA} only under either of the following conditions:
 - The charge pump is enabled (GCR[CPSEL]=1), the regulator is disabled (GCR[RVEN]=0), and VLL3 = V_{DDA} through the internal power switch (GCR[VSUPPLY]=0).
 - The resistor bias string is enabled (GCR[CPSEL]=0), the regulator is disabled (GCR[RVEN]=0), and VLL3 is connected to V_{DDA} externally (GCR[VSUPPLY]=1).

4 Dimensions

4.1 Obtaining package dimensions

Package dimensions are provided in package drawings.



To find a package drawing, go to **freescale.com** and perform a keyword search for the drawing's document number:

| If you want the drawing for this package | Then use this document number |
|--|-------------------------------|
| 64-pin LQFP | 98ASS23234W |
| 64-pin MAPBGA | 98ASA00420D |
| 100-pin LQFP | 98ASS23308W |
| 121-pin MAPBGA | 98ASA00344D |

5 Pinout

5.1 KL46 Signal Multiplexing and Pin Assignments

The following table shows the signals available on each pin and the locations of these pins on the devices supported by this document. The Port Control Module is responsible for selecting which ALT functionality is available on each pin.

| 121 BGA | 100 LQFP | 64 BGA | 64 LQFP | Pin Name | Default | ALT0 | ALT1 | ALT2 | ALT3 | ALT4 | ALT5 | ALT6 | ALT7 |
|------------|-------------|-----------|------------|----------|-----------------------|-----------------------------------|-------|-----------|----------|----------------|----------------------|----------|---------|
| E4 | 1 | A1 | 1 | PTE0 | DISABLED | LCD_P48 | PTE0 | SPI1_MISO | UART1_TX | RTC_ CLKOUT | CMP0_OUT | I2C1_SDA | LCD_P48 |
| E3 | 2 | B1 | 2 | PTE1 | DISABLED | LCD_P49 | PTE1 | SPI1_MOSI | UART1_RX | | SPI1_MISO | I2C1_SCL | LCD_P49 |
| E2 | 3 | _ | _ | PTE2 | DISABLED | LCD_P50 | PTE2 | SPI1_SCK | | | | | LCD_P50 |
| F4 | 4 | 1 | - | PTE3 | DISABLED | LCD_P51 | PTE3 | SPI1_MISO | | | SPI1_MOSI | | LCD_P51 |
| H7 | 5 | - | _ | PTE4 | DISABLED | LCD_P52 | PTE4 | SPI1_PCS0 | | | | | LCD_P52 |
| G4 | 6 | 1 | - | PTE5 | DISABLED | LCD_P53 | PTE5 | | | | | | LCD_P53 |
| F3 | 7 | ı | - | PTE6 | DISABLED | LCD_P54 | PTE6 | | | I2S0_MCLK | audioUSB_ SOF_OUT | | LCD_P54 |
| E6 | 8 | _ | 3 | VDD | VDD | VDD | | | | | | | |
| G7 | 9 | C4 | 4 | VSS | VSS | VSS | | | | | | | |
| L6 | _ | - | _ | VSS | VSS | VSS | | | | | | | |
| F1 | 10 | E1 | 5 | USB0_DP | USB0_DP | USB0_DP | | | | | | | |
| F2 | 11 | D1 | 6 | USB0_DM | USB0_DM | USB0_DM | | | | | | | |
| G1 | 12 | E2 | 7 | VOUT33 | VOUT33 | VOUT33 | | | | | | | |
| G2 | 13 | D2 | 8 | VREGIN | VREGIN | VREGIN | | | | | | | |
| H1 | 14 | 1 | ı | PTE16 | ADC0_DP1/ ADC0_SE1 | LCD_P55/ ADC0_DP1/ ADC0_SE1 | PTE16 | SPI0_PCS0 | UART2_TX | TPM_ CLKIN0 | | | LCD_P55 |



| 121 BGA | 100 LQFP | 64 BGA | 64 LQFP | Pin Name | Default | ALT0 | ALT1 | ALT2 | ALT3 | ALT4 | ALT5 | ALT6 | ALT7 |
|------------|-------------|-----------|------------|----------|-------------------------------------|-------------------------------------|-------|-----------|----------|----------------|-----------|------------------|-----------|
| H2 | 15 | 1 | - | PTE17 | ADC0_DM1/ ADC0_SE5a | LCD_P56/ ADC0_DM1/ ADC0_SE5a | PTE17 | SPI0_SCK | UART2_RX | TPM_ CLKIN1 | | LPTMR0_ ALT3 | LCD_P56 |
| J1 | 16 | ı | ı | PTE18 | ADC0_DP2/ ADC0_SE2 | LCD_P57/ ADC0_DP2/ ADC0_SE2 | PTE18 | SPI0_MOSI | | I2C0_SDA | SPI0_MISO | | LCD_P57 |
| J2 | 17 | ı | ı | PTE19 | ADC0_DM2/ ADC0_SE6a | LCD_P58/ ADC0_DM2/ ADC0_SE6a | PTE19 | SPI0_MISO | | 12C0_SCL | SPI0_MOSI | | LCD_P58 |
| K1 | 18 | G1 | 9 | PTE20 | ADC0_DP0/ ADC0_SE0 | LCD_P59/ ADC0_DP0/ ADC0_SE0 | PTE20 | | TPM1_CH0 | UARTO_TX | | | LCD_P59 |
| K2 | 19 | F1 | 10 | PTE21 | ADC0_DM0/ ADC0_SE4a | LCD_P60/ ADC0_DM0/ ADC0_SE4a | PTE21 | | TPM1_CH1 | UARTO_RX | | | LCD_P60 |
| L1 | 20 | G2 | 11 | PTE22 | ADC0_DP3/ ADC0_SE3 | ADC0_DP3/ ADC0_SE3 | PTE22 | | TPM2_CH0 | UART2_TX | | | |
| L2 | 21 | F2 | 12 | PTE23 | ADC0_DM3/ ADC0_SE7a | ADC0_DM3/ ADC0_SE7a | PTE23 | | TPM2_CH1 | UART2_RX | | | |
| F5 | 22 | F4 | 13 | VDDA | VDDA | VDDA | | | | | | | |
| G5 | 23 | G4 | 14 | VREFH | VREFH | VREFH | | | | | | | |
| G6 | 24 | G3 | 15 | VREFL | VREFL | VREFL | | | | | | | |
| F6 | 25 | F3 | 16 | VSSA | VSSA | VSSA | | | | | | | |
| L3 | 26 | H1 | 17 | PTE29 | CMP0_IN5/ ADC0_SE4b | CMP0_IN5/ ADC0_SE4b | PTE29 | | TPM0_CH2 | TPM_ CLKIN0 | | | |
| K5 | 27 | H2 | 18 | PTE30 | DAC0_OUT/ ADC0_SE23/ CMP0_IN4 | DAC0_OUT/ ADC0_SE23/ CMP0_IN4 | PTE30 | | TPM0_CH3 | TPM_ CLKIN1 | | | |
| L4 | 28 | H3 | 19 | PTE31 | DISABLED | | PTE31 | | TPM0_CH4 | | | | |
| L5 | 29 | - | _ | VSS | VSS | VSS | | | | | | | |
| K6 | 30 | _ | _ | VDD | VDD | VDD | | | | | | | |
| H5 | 31 | H4 | 20 | PTE24 | DISABLED | | PTE24 | | TPM0_CH0 | | I2C0_SCL | | |
| J5 | 32 | H5 | 21 | PTE25 | DISABLED | | PTE25 | | TPM0_CH1 | | I2C0_SDA | | |
| H6 | 33 | 1 | - | PTE26 | DISABLED | | PTE26 | | TPM0_CH5 | | | RTC_ CLKOUT | USB_CLKIN |
| J6 | 34 | D3 | 22 | PTA0 | SWD_CLK | TSI0_CH1 | PTA0 | | TPM0_CH5 | | | | SWD_CLK |
| H8 | 35 | D4 | 23 | PTA1 | DISABLED | TSI0_CH2 | PTA1 | UARTO_RX | TPM2_CH0 | | | | |
| J7 | 36 | E5 | 24 | PTA2 | DISABLED | TSI0_CH3 | PTA2 | UART0_TX | TPM2_CH1 | | | | |
| H9 | 37 | D5 | 25 | PTA3 | SWD_DIO | TSI0_CH4 | PTA3 | I2C1_SCL | TPM0_CH0 | | | | SWD_DIO |
| J8 | 38 | G5 | 26 | PTA4 | NMI_b | TSI0_CH5 | PTA4 | I2C1_SDA | TPM0_CH1 | | | | NMI_b |
| K7 | 39 | F5 | 27 | PTA5 | DISABLED | | PTA5 | USB_CLKIN | TPM0_CH2 | | | I2S0_TX_ BCLK | |
| E5 | _ | _ | _ | VDD | VDD | VDD | | | | | | | |
| G3 | - | 1 | - | VSS | VSS | VSS | | | | | | | |
| K3 | 40 | _ | _ | PTA6 | DISABLED | | PTA6 | | TPM0_CH3 | | | | |



Pinout

| 121 BGA | 100 LQFP | 64 BGA | 64 LQFP | Pin Name | Default | ALT0 | ALT1 | ALT2 | ALT3 | ALT4 | ALT5 | ALT6 | ALT7 |
|------------|-------------|-----------|------------|------------------|-----------------------------------|-----------------------------------|------------------|-----------|----------|------------------|-----------|------------------|-----------|
| H4 | 41 | _ | _ | PTA7 | DISABLED | | PTA7 | | TPM0_CH4 | | | | |
| K8 | 42 | H6 | 28 | PTA12 | DISABLED | | PTA12 | | TPM1_CH0 | | | 12S0_TXD0 | |
| L8 | 43 | G6 | 29 | PTA13 | DISABLED | | PTA13 | | TPM1_CH1 | | | I2S0_TX_FS | |
| K9 | 44 | - | 1 | PTA14 | DISABLED | | PTA14 | SPI0_PCS0 | UARTO_TX | | | I2S0_RX_ BCLK | 12S0_TXD0 |
| L9 | 45 | 1 | | PTA15 | DISABLED | | PTA15 | SPI0_SCK | UARTO_RX | | | I2S0_RXD0 | |
| J10 | 46 | 1 | | PTA16 | DISABLED | | PTA16 | SPI0_MOSI | | | SPI0_MISO | I2S0_RX_FS | I2S0_RXD0 |
| H10 | 47 | - | _ | PTA17 | DISABLED | | PTA17 | SPI0_MISO | | | SPI0_MOSI | I2S0_MCLK | |
| L10 | 48 | G7 | 30 | VDD | VDD | VDD | | | | | | | |
| K10 | 49 | H7 | 31 | VSS | VSS | VSS | | | | | | | |
| L11 | 50 | H8 | 32 | PTA18 | EXTAL0 | EXTAL0 | PTA18 | | UART1_RX | TPM_ CLKIN0 | | | |
| K11 | 51 | G8 | 33 | PTA19 | XTAL0 | XTAL0 | PTA19 | | UART1_TX | TPM_ CLKIN1 | | LPTMR0_ ALT1 | |
| J11 | 52 | F8 | 34 | PTA20 | RESET_b | | PTA20 | | | | | | RESET_b |
| G11 | 53 | F7 | 35 | PTB0/ LLWU_P5 | LCD_P0/ ADC0_SE8/ TSI0_CH0 | LCD_P0/ ADC0_SE8/ TSI0_CH0 | PTB0/ LLWU_P5 | I2C0_SCL | TPM1_CH0 | | | | LCD_P0 |
| G10 | 54 | F6 | 36 | PTB1 | LCD_P1/ ADC0_SE9/ TSI0_CH6 | LCD_P1/ ADC0_SE9/ TSI0_CH6 | PTB1 | I2C0_SDA | TPM1_CH1 | | | | LCD_P1 |
| G9 | 55 | E7 | 37 | PTB2 | LCD_P2/ ADC0_SE12/ TSI0_CH7 | LCD_P2/ ADC0_SE12/ TSI0_CH7 | PTB2 | I2C0_SCL | TPM2_CH0 | | | | LCD_P2 |
| G8 | 56 | E8 | 38 | PTB3 | LCD_P3/ ADC0_SE13/ TSI0_CH8 | LCD_P3/ ADC0_SE13/ TSI0_CH8 | PTB3 | I2C0_SDA | TPM2_CH1 | | | | LCD_P3 |
| E11 | 57 | _ | _ | PTB7 | LCD_P7 | LCD_P7 | PTB7 | | | | | | LCD_P7 |
| D11 | 58 | _ | _ | PTB8 | LCD_P8 | LCD_P8 | PTB8 | SPI1_PCS0 | EXTRG_IN | | | | LCD_P8 |
| E10 | 59 | _ | _ | PTB9 | LCD_P9 | LCD_P9 | PTB9 | SPI1_SCK | | | | | LCD_P9 |
| D10 | 60 | _ | _ | PTB10 | LCD_P10 | LCD_P10 | PTB10 | SPI1_PCS0 | | | | | LCD_P10 |
| C10 | 61 | - | _ | PTB11 | LCD_P11 | LCD_P11 | PTB11 | SPI1_SCK | | | | | LCD_P11 |
| B10 | 62 | E6 | 39 | PTB16 | LCD_P12/ TSI0_CH9 | LCD_P12/ TSI0_CH9 | PTB16 | SPI1_MOSI | UARTO_RX | TPM_ CLKIN0 | SPI1_MISO | | LCD_P12 |
| E9 | 63 | D7 | 40 | PTB17 | LCD_P13/ TSI0_CH10 | LCD_P13/ TSI0_CH10 | PTB17 | SPI1_MISO | UARTO_TX | TPM_ CLKIN1 | SPI1_MOSI | | LCD_P13 |
| D9 | 64 | D6 | 41 | PTB18 | LCD_P14/ TSI0_CH11 | LCD_P14/ TSI0_CH11 | PTB18 | | TPM2_CH0 | I2S0_TX_ BCLK | | | LCD_P14 |
| C9 | 65 | C7 | 42 | PTB19 | LCD_P15/ TSI0_CH12 | LCD_P15/ TSI0_CH12 | PTB19 | | TPM2_CH1 | I2S0_TX_FS | | | LCD_P15 |
| F10 | 66 | _ | 1 | PTB20 | LCD_P16 | LCD_P16 | PTB20 | | | | | CMP0_OUT | LCD_P16 |
| F9 | 67 | _ | 1 | PTB21 | LCD_P17 | LCD_P17 | PTB21 | | | | | | LCD_P17 |
| F8 | 68 | _ | ı | PTB22 | LCD_P18 | LCD_P18 | PTB22 | | | | | | LCD_P18 |
| E8 | 69 | - | _ | PTB23 | LCD_P19 | LCD_P19 | PTB23 | | | | | | LCD_P19 |





| 121 BGA | 100 LQFP | 64 BGA | 64 LQFP | Pin Name | Default | ALT0 | ALT1 | ALT2 | ALT3 | ALT4 | ALT5 | ALT6 | ALT7 |
|------------|-------------|-----------|------------|--------------------------------|-------------------------------------|-------------------------------------|--------------------------------|-----------|----------------------|----------------------|-----------|------------------|---------|
| В9 | 70 | D8 | 43 | PTC0 | LCD_P20/ ADC0_SE14/ TSI0_CH13 | LCD_P20/ ADC0_SE14/ TSI0_CH13 | PTC0 | | EXTRG_IN | audioUSB_ SOF_OUT | CMP0_OUT | I2S0_TXD0 | LCD_P20 |
| D8 | 71 | C6 | 44 | PTC1/ LLWU_P6/ RTC_CLKIN | LCD_P21/ ADC0_SE15/ TSI0_CH14 | LCD_P21/ ADC0_SE15/ TSI0_CH14 | PTC1/ LLWU_P6/ RTC_CLKIN | I2C1_SCL | | TPM0_CH0 | | 12S0_TXD0 | LCD_P21 |
| C8 | 72 | В7 | 45 | PTC2 | LCD_P22/ ADC0_SE11/ TSI0_CH15 | LCD_P22/ ADC0_SE11/ TSI0_CH15 | PTC2 | I2C1_SDA | | TPM0_CH1 | | I2S0_TX_FS | LCD_P22 |
| B8 | 73 | C8 | 46 | PTC3/ LLWU_P7 | LCD_P23 | LCD_P23 | PTC3/ LLWU_P7 | | UART1_RX | TPM0_CH2 | CLKOUT | I2S0_TX_ BCLK | LCD_P23 |
| F7 | 74 | E3 | 47 | VSS | VSS | VSS | | | | | | | |
| E7 | - | E4 | - | VDD | VDD | VDD | | | | | | | |
| A11 | 75 | C5 | 48 | VLL3 | VLL3 | VLL3 | | | | | | | |
| A10 | 76 | A6 | 49 | VLL2 | VLL2 | VLL2/ LCD_P4 | PTC20 | | | | | | LCD_P4 |
| A9 | 77 | B5 | 50 | VLL1 | VLL1 | VLL1/ LCD_P5 | PTC21 | | | | | | LCD_P5 |
| B11 | 78 | В4 | 51 | VCAP2 | VCAP2 | VCAP2/ LCD_P6 | PTC22 | | | | | | LCD_P6 |
| C11 | 79 | A5 | 52 | VCAP1 | VCAP1 | VCAP1/ LCD_P39 | PTC23 | | | | | | LCD_P39 |
| A8 | 80 | B8 | 53 | PTC4/ LLWU_P8 | LCD_P24 | LCD_P24 | PTC4/ LLWU_P8 | SPI0_PCS0 | UART1_TX | TPM0_CH3 | I2S0_MCLK | | LCD_P24 |
| D7 | 81 | A8 | 54 | PTC5/ LLWU_P9 | LCD_P25 | LCD_P25 | PTC5/ LLWU_P9 | SPI0_SCK | LPTMR0_ ALT2 | 12S0_RXD0 | | CMP0_OUT | LCD_P25 |
| C7 | 82 | A7 | 55 | PTC6/ LLWU_P10 | LCD_P26/ CMP0_IN0 | LCD_P26/ CMP0_IN0 | PTC6/ LLWU_P10 | SPI0_MOSI | EXTRG_IN | I2S0_RX_ BCLK | SPI0_MISO | I2S0_MCLK | LCD_P26 |
| B7 | 83 | В6 | 56 | PTC7 | LCD_P27/ CMP0_IN1 | LCD_P27/ CMP0_IN1 | PTC7 | SPI0_MISO | audioUSB_ SOF_OUT | 12S0_RX_FS | SPI0_MOSI | | LCD_P27 |
| A7 | 84 | - | 1 | PTC8 | LCD_P28/ CMP0_IN2 | LCD_P28/ CMP0_IN2 | PTC8 | I2C0_SCL | TPM0_CH4 | I2S0_MCLK | | | LCD_P28 |
| D6 | 85 | - | 1 | PTC9 | LCD_P29/ CMP0_IN3 | LCD_P29/ CMP0_IN3 | PTC9 | I2C0_SDA | TPM0_CH5 | I2S0_RX_ BCLK | | | LCD_P29 |
| C6 | 86 | _ | _ | PTC10 | LCD_P30 | LCD_P30 | PTC10 | I2C1_SCL | | I2S0_RX_FS | | | LCD_P30 |
| C5 | 87 | - | - | PTC11 | LCD_P31 | LCD_P31 | PTC11 | I2C1_SDA | | I2S0_RXD0 | | | LCD_P31 |
| B6 | 88 | - | - | PTC12 | LCD_P32 | LCD_P32 | PTC12 | | | TPM_ CLKIN0 | | | LCD_P32 |
| A6 | 89 | - | - | PTC13 | LCD_P33 | LCD_P33 | PTC13 | | | TPM_ CLKIN1 | | | LCD_P33 |
| D5 | 90 | _ | _ | PTC16 | LCD_P36 | LCD_P36 | PTC16 | | | | | | LCD_P36 |
| C4 | 91 | _ | _ | PTC17 | LCD_P37 | LCD_P37 | PTC17 | | | | | | LCD_P37 |
| B4 | 92 | - | - | PTC18 | LCD_P38 | LCD_P38 | PTC18 | | | | | | LCD_P38 |
| D4 | 93 | C3 | 57 | PTD0 | LCD_P40 | LCD_P40 | PTD0 | SPI0_PCS0 | | TPM0_CH0 | | | LCD_P40 |



Pinout

| 121 BGA | 100 LQFP | 64 BGA | 64 LQFP | Pin Name | Default | ALT0 | ALT1 | ALT2 | ALT3 | ALT4 | ALT5 | ALT6 | ALT7 |
|------------|-------------|-----------|------------|-------------------|-----------------------|-----------------------|-------------------|-----------|----------|----------|-----------|------|---------|
| D3 | 94 | A4 | 58 | PTD1 | LCD_P41/ ADC0_SE5b | LCD_P41/ ADC0_SE5b | PTD1 | SPI0_SCK | | TPM0_CH1 | | | LCD_P41 |
| C3 | 95 | C2 | 59 | PTD2 | LCD_P42 | LCD_P42 | PTD2 | SPI0_MOSI | UART2_RX | TPM0_CH2 | SPI0_MISO | | LCD_P42 |
| В3 | 96 | В3 | 60 | PTD3 | LCD_P43 | LCD_P43 | PTD3 | SPI0_MISO | UART2_TX | TPM0_CH3 | SPI0_MOSI | | LCD_P43 |
| A3 | 97 | A3 | 61 | PTD4/ LLWU_P14 | LCD_P44 | LCD_P44 | PTD4/ LLWU_P14 | SPI1_PCS0 | UART2_RX | TPM0_CH4 | | | LCD_P44 |
| A2 | 98 | C1 | 62 | PTD5 | LCD_P45/ ADC0_SE6b | LCD_P45/ ADC0_SE6b | PTD5 | SPI1_SCK | UART2_TX | TPM0_CH5 | | | LCD_P45 |
| B2 | 99 | B2 | 63 | PTD6/ LLWU_P15 | LCD_P46/ ADC0_SE7b | LCD_P46/ ADC0_SE7b | PTD6/ LLWU_P15 | SPI1_MOSI | UARTO_RX | | SPI1_MISO | | LCD_P46 |
| A1 | 100 | A2 | 64 | PTD7 | LCD_P47 | LCD_P47 | PTD7 | SPI1_MISO | UARTO_TX | | SPI1_MOSI | | LCD_P47 |
| J3 | _ | _ | _ | NC | NC | NC | | | | | | | |
| НЗ | _ | _ | _ | NC | NC | NC | | | | | | | |
| K4 | _ | _ | _ | NC | NC | NC | | | | | | | |
| L7 | _ | _ | _ | NC | NC | NC | | | | | | | |
| J9 | _ | _ | _ | NC | NC | NC | | | | | | | |
| J4 | _ | _ | _ | NC | NC | NC | | | | | | | |
| H11 | _ | _ | _ | NC | NC | NC | | | | | | | |
| F11 | _ | 1 | _ | NC | NC | NC | | | | | | | |
| A5 | _ | 1 | _ | NC | NC | NC | | | | | | | |
| B5 | _ | 1 | _ | NC | NC | NC | | | | | | | |
| A4 | _ | _ | _ | NC | NC | NC | | | | | | | |
| B1 | _ | _ | _ | NC | NC | NC | | | | | | | |
| C2 | _ | - | - | NC | NC | NC | | | | | | | |
| C1 | _ | - | _ | NC | NC | NC | | | | | | | |
| D2 | _ | _ | _ | NC | NC | NC | | | | | | | |
| D1 | _ | _ | _ | NC | NC | NC | | | | | | | |
| E1 | _ | _ | _ | NC | NC | NC | | | | | | | |

5.2 KL46 pinouts

The following figures show the pinout diagrams for the devices supported by this document. Many signals may be multiplexed onto a single pin. To determine what signals can be used on which pin, ssee KL46 Signal Multiplexing and Pin Assignments.



| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | _ |
|---|---------|-------------------|-------------------|-------|-------|-------|-------------------|--------------------------------|-------|-------|------------------|---|
| Α | PTD7 | PTD5 | PTD4/ LLWU_P14 | NC | NC | PTC13 | PTC8 | PTC4/ LLWU_P8 | VLL1 | VLL2 | VLL3 | А |
| В | NC | PTD6/ LLWU_P15 | PTD3 | PTC18 | NC | PTC12 | PTC7 | PTC3/ LLWU_P7 | PTC0 | PTB16 | VCAP2 | В |
| С | NC | NC | PTD2 | PTC17 | PTC11 | PTC10 | PTC6/ LLWU_P10 | PTC2 | PTB19 | PTB11 | VCAP1 | С |
| D | NC | NC | PTD1 | PTD0 | PTC16 | PTC9 | PTC5/ LLWU_P9 | PTC1/ LLWU_P6/ RTC_CLKIN | PTB18 | PTB10 | PTB8 | D |
| E | NC | PTE2 | PTE1 | PTE0 | VDD | VDD | VDD | PTB23 | PTB17 | PTB9 | PTB7 | E |
| F | USB0_DP | USB0_DM | PTE6 | PTE3 | VDDA | VSSA | vss | PTB22 | PTB21 | PTB20 | NC | F |
| G | VOUT33 | VREGIN | VSS | PTE5 | VREFH | VREFL | vss | PTB3 | PTB2 | PTB1 | PTB0/ LLWU_P5 | G |
| н | PTE16 | PTE17 | NC | PTA7 | PTE24 | PTE26 | PTE4 | PTA1 | PTA3 | PTA17 | NC | н |
| J | PTE18 | PTE19 | NC | NC | PTE25 | PTA0 | PTA2 | PTA4 | NC | PTA16 | PTA20 | J |
| Κ | PTE20 | PTE21 | PTA6 | NC | PTE30 | VDD | PTA5 | PTA12 | PTA14 | vss | PTA19 | к |
| L | PTE22 | PTE23 | PTE29 | PTE31 | VSS | VSS | NC | PTA13 | PTA15 | VDD | PTA18 | L |
| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | I |

Figure 23. KL46 121-pin BGA pinout diagram



Pinout

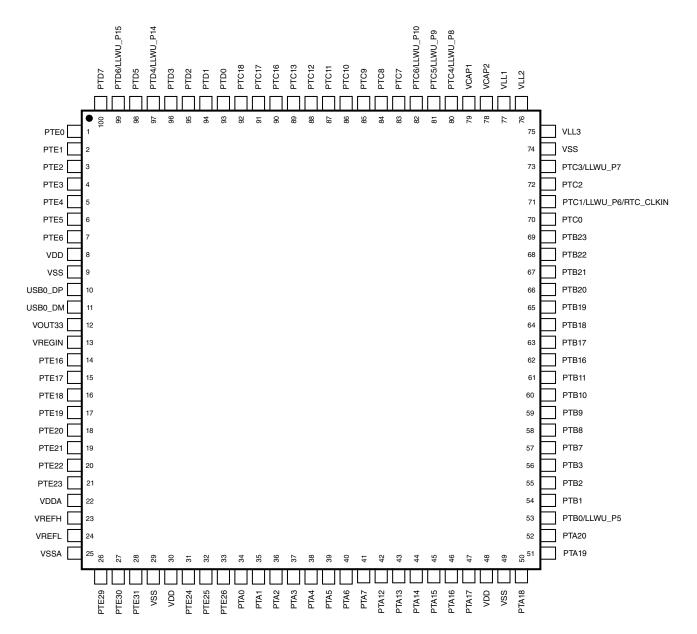


Figure 24. KL46 100-pin LQFP pinout diagram



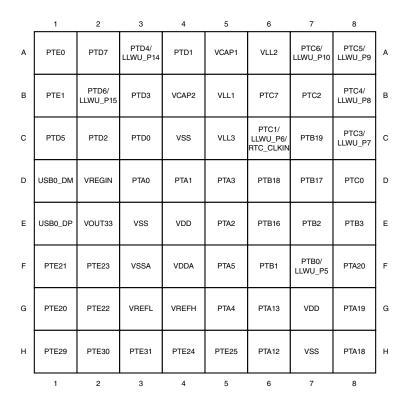


Figure 25. KL46 64-pin BGA pinout diagram



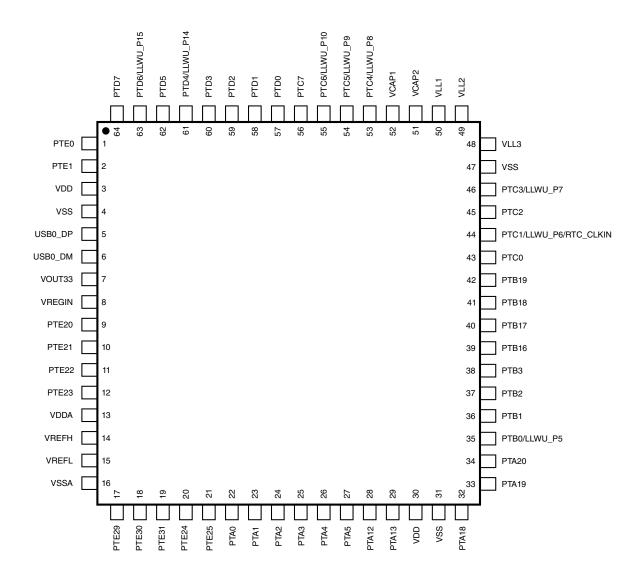


Figure 26. KL46 64-pin LQFP pinout diagram

6 Ordering parts

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6.1 Determining valid orderable parts

Valid orderable part numbers are provided on the web. To determine the orderable part numbers for this device, go to **freescale.com** and perform a part number search for the following device numbers: PKL46 and MKL46

7 Part identification

7.1 Description

Part numbers for the chip have fields that identify the specific part. You can use the values of these fields to determine the specific part you have received.

7.2 Format

Part numbers for this device have the following format:

Q KL## A FFF R T PP CC N

7.3 Fields

This table lists the possible values for each field in the part number (not all combinations are valid):

Table 42. Part number fields descriptions

| Field | Description | Values |
|-------|---------------------------|--|
| Q | Qualification status | M = Fully qualified, general market flow P = Prequalification |
| KL## | Kinetis family | • KL46 |
| Α | Key attribute | • Z = Cortex-M0+ |
| FFF | Program flash memory size | 128 = 128 KB256 = 256 KB |
| R | Silicon revision | (Blank) = MainA = Revision after main |
| Т | Temperature range (°C) | • V = -40 to 105 |
| PP | Package identifier | LH = 64 LQFP (10 mm x 10 mm) MP = 64 MAPBGA (5 mm x 5 mm) |

Terminology and guidelines

Table 42. Part number fields descriptions (continued)

| Field | Description | Values |
|-------|-----------------------------|--|
| | | LL = 100 LQFP (14 mm x 14 mm) MC = 121 MAPBGA (8 mm x 8 mm) |
| CC | Maximum CPU frequency (MHz) | • 4 = 48 MHz |
| N | Packaging type | R = Tape and reel |

Example 7.4

This is an example part number:

MKL46Z256VMC4

Terminology and guidelines

Definition: Operating requirement 8.1

An *operating requirement* is a specified value or range of values for a technical characteristic that you must guarantee during operation to avoid incorrect operation and possibly decreasing the useful life of the chip.

Example 8.1.1

This is an example of an operating requirement:

| Symbol | Description | Min. | Max. | Unit |
|----------|---------------------------|------|------|------|
| V_{DD} | 1.0 V core supply voltage | 0.9 | 1.1 | V |

Definition: Operating behavior 8.2

Unless otherwise specified, an *operating behavior* is a specified value or range of values for a technical characteristic that are guaranteed during operation if you meet the operating requirements and any other specified conditions.



8.3 Definition: Attribute

An *attribute* is a specified value or range of values for a technical characteristic that are guaranteed, regardless of whether you meet the operating requirements.

8.3.1 Example

This is an example of an attribute:

| Symbol | Description | Min. | Max. | Unit |
|--------|---------------------------------|------|------|------|
| CIN_D | Input capacitance: digital pins | _ | 7 | pF |

8.4 Definition: Rating

A *rating* is a minimum or maximum value of a technical characteristic that, if exceeded, may cause permanent chip failure:

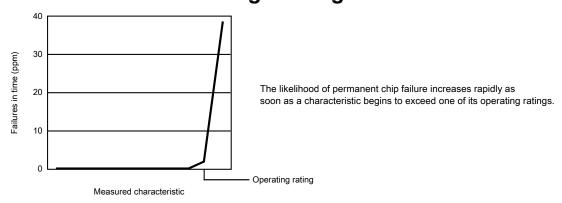
- *Operating ratings* apply during operation of the chip.
- Handling ratings apply when the chip is not powered.

8.4.1 Example

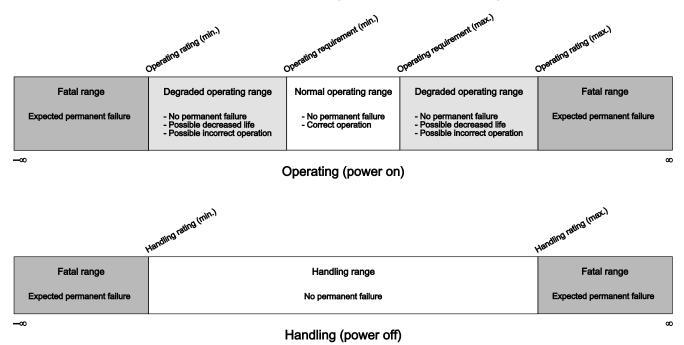
This is an example of an operating rating:

| Symbol | Description | Min. | Max. | Unit |
|----------|---------------------------|------|------|------|
| V_{DD} | 1.0 V core supply voltage | -0.3 | 1.2 | V |

8.5 Result of exceeding a rating



8.6 Relationship between ratings and operating requirements



8.7 Guidelines for ratings and operating requirements

Follow these guidelines for ratings and operating requirements:

- Never exceed any of the chip's ratings.
- During normal operation, don't exceed any of the chip's operating requirements.
- If you must exceed an operating requirement at times other than during normal operation (for example, during power sequencing), limit the duration as much as possible.



8.8 Definition: Typical value

A typical value is a specified value for a technical characteristic that:

- Lies within the range of values specified by the operating behavior
- Given the typical manufacturing process, is representative of that characteristic during operation when you meet the typical-value conditions or other specified conditions

Typical values are provided as design guidelines and are neither tested nor guaranteed.

8.8.1 **Example 1**

This is an example of an operating behavior that includes a typical value:

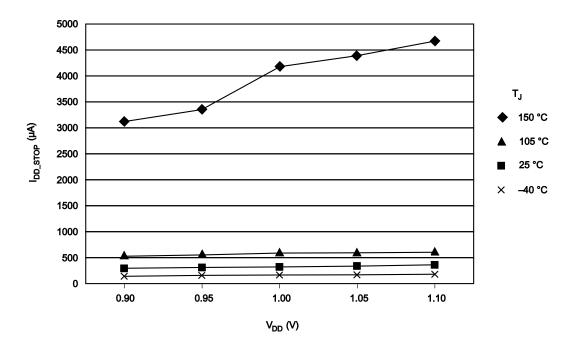
| Symbol | Description | Min. | Тур. | Max. | Unit |
|-----------------|--|------|------|------|------|
| I _{WP} | Digital I/O weak pullup/pulldown current | 10 | 70 | 130 | μΑ |

8.8.2 Example 2

This is an example of a chart that shows typical values for various voltage and temperature conditions:



Revision history



8.9 Typical value conditions

Typical values assume you meet the following conditions (or other conditions as specified):

Table 43. Typical value conditions

| Symbol Description | | Value | Unit |
|--------------------|----------------------|-------|------|
| T _A | Ambient temperature | 25 | °C |
| V_{DD} | 3.3 V supply voltage | 3.3 | V |

9 Revision history

The following table provides a revision history for this document.

Table 44. Revision history

| Rev. No. | Date | Substantial Changes |
|----------|--------|--|
| 3 | 3/2014 | Updated the front page and restructured the chapters Updated Voltage and current operating behaviors Updated EMC radiated emissions operating behaviors Updated Power mode transition operating behaviors |



Table 44. Revision history (continued)

| Rev. No. | Date | Substantial Changes |
|----------|---------|--|
| | | Updated Capacitance attributes Updated footnote in the Device clock specifications Added thermal attributes of 64-pin MAPBGA in the Thermal attributes Added V _{REFH} and V _{REFL} in the 16-bit ADC electrical characteristics Updated footnote to the V _{DACR} in the 12-bit DAC operating requirements Updated I _{LOADrun} and I _{LIM} in the USB VREG electrical specifications Added Inter-Integrated Circuit Interface (I2C) timing |
| 4 | 5/2014 | Updated Power consumption operating behaviors Updated USB electrical specifications Updated Definition: Operating behavior |
| 5 | 08/2014 | Updated related source in the front page Updated Power consumption operating behaviors Updated the note in USB electrical specifications |





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